

# MPC5748G

## MPC5748G Microcontroller Datasheet

### Features

- 2 x 160 MHz Power Architecture® e200Z4 Dual issue, 32-bit CPU
  - Single precision floating point operations
  - 8 KB instruction cache and 4 KB data cache
  - Variable length encoding (VLE) for significant code density improvements
- 1 x 80 MHz Power Architecture® e200Z2 Single issue, 32-bit CPU
  - Using variable length encoding (VLE) for significant code size footprint reduction
- End to end ECC
  - All bus masters, for example, cores generate single error correction, double error detection (SECDED) code for every bus transaction
  - SECDED covers 64-bit data and 29-bit address
- Memory interfaces
  - 6 MB on-chip flash supported with the flash controller
  - 3 x flash page buffers (3 port flash controller)
  - 768 KB on-chip SRAM across three RAM ports
- Clock interfaces
  - 8-40 MHz external crystal (FXOSC)
  - 16 MHz IRC (FIRC)
  - 128 KHz IRC (SIRC)
  - 32 KHz external crystal (SXOSC)
  - Clock Monitor Unit (CMU)
  - Frequency modulated phase-locked loop (FMPLL)
  - Real Time Counter (RTC)
- System Memory Protection Unit (SMPU) with up to 32 region descriptors and 16-byte region granularity
- 16 Semaphores to manage access to shared resource
- Interrupt controller (INTC) capable of routing interrupts to any CPU
- Multiple crossbar switch architecture for concurrent access to peripherals, flash, and RAM from multiple bus masters
- 32-channels eDMA controller with multiple transfer request sources using DMAMUX
- Boot Assist Flash (BAF) supports internal flash programming via a serial link (LIN / SCI)
- Analog
  - Two analog-to-digital converters (ADC), one 10-bit and one 12-bit
  - Three analogue comparators
  - Cross Trigger Unit to enable synchronization of ADC conversions with a timer event from the eMIOS or from the PIT
- Communication
  - Four Deserial Peripheral Interface (DSPI)
  - Six Serial Peripheral interface (SPI)
  - 18 serial communication interface (LIN) modules
  - Eight enhanced FlexCAN3 with FD support
  - Four inter-IC communication interface (IIC)
  - One USB OTG Controller (USB\_0) and One USB SPH Controller (USB\_1) with ULPI Interface.
  - ENET complex (10/100 Ethernet) that supports Multi queue with AVB support, 1588, and MII/RMII
  - 2 x ENET with L2 switch
  - Secure Digital Hardware Controller (uSDHC)
  - Dual-channel FlexRay Controller
- Audio
  - 3 x Synchronous Audio Interface (SAI)
  - Fractional clock dividers (FCD) operating in conjunction with the SAIs
- Configurable I/O domains supporting FLEXCAN, LINFlex, Ethernet, USB, MLB, uSDHC and general I/O
- Supports wake-up from low power modes via the WKUP controller
- On-chip voltage regulator (VREG)

This document contains information on a new product. Specifications and information herein are subject to change without notice.

- Debug functionality
  - e200Z2 core: NDI per IEEE-ISTO 5001-2008 Class3+
  - e200Z4 core(s): NDI per IEEE-ISTO 5001-2008 Class 3+
- Timer
  - 16 Periodic Interrupt Timers (PITs)
  - Three System Timer Module (STM)
  - Four Software WatchDog Timers (SWT)
  - 96 Configurable Enhanced Modular Input Output Subsystem (eMIOS) channels
- Device/board boundary Scan testing supported with per Joint Test Action Group (JTAG) of IEEE (IEEE 1149.1) and 1149.7 (cJTAG)
- Security
  - Hardware Security Module (HSMv2)
  - Password and Device Security (PASS and TDM) supporting advanced censorship and life-cycle management
  - One Fault Collection and Control Unit (FCCU) to collect faults and issue interrupts
- Functional Safety
  - ISO26262 ASIL compliance
- Multiple operating modes
  - Includes enhanced low power operation

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# 1 Ordering parts

## 1.1 Determining valid orderable parts

To determine the orderable part numbers for this device, go to [www.freescale.com](http://www.freescale.com) and perform a part number search for the following device number: MPC5748G .

## 1.2 Ordering Information

|                                 |   |    |    |   |   |   |   |    |   |    |   |   |
|---------------------------------|---|----|----|---|---|---|---|----|---|----|---|---|
| Example Code                    | P | PC | 57 | 4 | 8 | G | S | K0 | M | MJ | 6 | R |
| Qualification Status            |   |    |    |   |   |   |   |    |   |    |   |   |
| Power Architecture              |   |    |    |   |   |   |   |    |   |    |   |   |
| Automotive Platform             |   |    |    |   |   |   |   |    |   |    |   |   |
| Core Version                    |   |    |    |   |   |   |   |    |   |    |   |   |
| Flash Size (core dependent)     |   |    |    |   |   |   |   |    |   |    |   |   |
| Product                         |   |    |    |   |   |   |   |    |   |    |   |   |
| Optional fields                 |   |    |    |   |   |   |   |    |   |    |   |   |
| Fab and mask indicator          |   |    |    |   |   |   |   |    |   |    |   |   |
| Temperature spec.               |   |    |    |   |   |   |   |    |   |    |   |   |
| Package Code                    |   |    |    |   |   |   |   |    |   |    |   |   |
| CPU Frequency                   |   |    |    |   |   |   |   |    |   |    |   |   |
| R = Tape & Reel (blank if Tray) |   |    |    |   |   |   |   |    |   |    |   |   |

|                                                                                                     |                                                                                                                                                                            |                                                                                                  |
|-----------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|
| <b>Qualification Status</b><br>P = Engineering samples<br>S = Automotive qualified                  | <b>Product Version</b><br>C = Body Control Feature Set<br>G = Gateway Feature Set                                                                                          | <b>Package Code</b><br>KU = 176 LQFP EP<br>MJ = 256 MAPBGA<br>MN = 324 MAPBGA                    |
| <b>PC = Power Architecture</b><br><br><b>Automotive Platform</b><br>57 = Power Architecture in 55nm | <b>Optional fields</b><br>S = HSM (Security Module) Available<br>F = CAN FD available on CAN modules<br>B = Both HSM and CAN FD available<br>Blank = Feature not available | <b>CPU Frequency</b><br>2 = Each z4 operates up to 120 MHz<br>6 = Each z4 operates up to 160 MHz |
| <b>Core Version</b><br>4 = e200z4 Core Version (highest core version in the case of multiple cores) | <b>Fab and mask version indicator</b><br>K = TSMC Fab<br>#(0,1,etc.) = Version of the maskset, like rev. 0=0N65H                                                           | <b>Shipping Method</b><br>R = Tape and reel<br>Blank = Tray                                      |
| <b>Flash Memory Size</b><br>6 = 3 MB<br>7 = 4 MB<br>8 = 6 MB                                        | <b>Temperature spec.</b><br>C = -40.C to +85.C Ta<br>V = -40.C to +105.C Ta<br>M = -40.C to +125.C Ta                                                                      |                                                                                                  |

## 2 General

### 2.1 Introduction

The electrical specifications are preliminary and are initial evaluation. These specifications are not fully tested or guaranteed at this early stage of the product life cycle. Finalized specifications will be published after complete characterization and device qualifications have been completed.

### 2.2 Absolute maximum ratings

#### NOTE

Functional operating conditions appear in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maximum values is not guaranteed.

Stress beyond the listed maximum values may affect device reliability or cause permanent damage to the device.

**Table 1. Absolute maximum ratings**

| Symbol                                                              | Parameter                                                                          | Conditions                                                            | Min  | Max <sup>1</sup>      | Unit |
|---------------------------------------------------------------------|------------------------------------------------------------------------------------|-----------------------------------------------------------------------|------|-----------------------|------|
| $V_{DD\_HV\_A}$ , $V_{DD\_HV\_B}$ ,<br>$V_{DD\_HV\_C}$ <sup>2</sup> | 3.3 V - 5.5V input/output supply voltage                                           | —                                                                     | −0.3 | 6.0                   | V    |
| $V_{SS\_HV}$                                                        | Input/output ground voltage                                                        | —                                                                     | −0.1 | 0.1                   | V    |
| $V_{DD\_HV\_FLA}$ <sup>3, 4</sup>                                   | 3.3 V flash supply voltage (when supplying from an external source in bypass mode) | —                                                                     | −0.3 | 3.63                  | V    |
| $V_{DD\_LP\_DEC}$ <sup>5</sup>                                      | Decoupling pin for low power regulators <sup>6</sup>                               | —                                                                     | −0.3 | 1.32                  | V    |
| $V_{DD\_HV\_ADC1\_REF}$ <sup>7</sup>                                | 3.3 V / 5.0 V ADC1 high reference voltage                                          | —                                                                     | −0.3 | 6                     | V    |
| $V_{DD\_HV\_ADC0}$<br>$V_{DD\_HV\_ADC1}$                            | 3.3 V to 5.5V ADC supply voltage                                                   | —                                                                     | −0.3 | 6.0                   | V    |
| $V_{SS\_HV\_ADC0}$<br>$V_{SS\_HV\_ADC1}$                            | 3.3V to 5.5V ADC supply ground                                                     | —                                                                     | −0.1 | 0.1                   | V    |
| $V_{INA}$                                                           | Voltage on analog pin with respect to ground ( $V_{SS\_HV}$ )                      | —                                                                     | −0.3 | $V_{DD\_HV\_x} + 0.3$ | V    |
| $V_{IN}$                                                            | Voltage on any digital pin with respect to ground ( $V_{SS\_HV}$ )                 | Relative to $V_{DD\_HV\_A}$ ,<br>$V_{DD\_HV\_B}$ ,<br>$V_{DD\_HV\_C}$ | −0.3 | $V_{DD\_HV\_x} + 0.3$ | V    |

Table continues on the next page...

**Table 1. Absolute maximum ratings (continued)**

| Symbol                      | Parameter                                                             | Conditions | Min         | Max <sup>1</sup> | Unit |
|-----------------------------|-----------------------------------------------------------------------|------------|-------------|------------------|------|
| I <sub>INJPAD</sub>         | Injected input current on any pin during overload condition           | Always     | –5          | 5                | mA   |
| I <sub>INJSUM</sub>         | Absolute sum of all injected input currents during overload condition | —          | –50         | 50               | mA   |
| T <sub>ramp</sub>           | Supply ramp rate                                                      | —          | 0.5 V / min | 100V/ms          | —    |
| T <sub>a</sub> <sup>8</sup> | Ambient temperature                                                   | —          | –40         | 125              | °C   |
| T <sub>STG</sub>            | Storage temperature                                                   | —          | –55         | 165              | °C   |

1. Absolute maximum voltages are currently maximum burn-in voltages. Absolute maximum specifications for device stress have not yet been determined.
2. VDD\_HV\_B and VDD\_HV\_C are common together on the 176 LQFP package.
3. VDD\_HV\_FL A must be connected to VDD\_HV\_A when VDD\_HV\_A = 3.3V
4. VDD\_HV\_FL A must be disconnected from ANY power sources when VDD\_HV\_A = 5V
5. This pin should be decoupled with low ESR 1 µF capacitor.
6. Not available for input voltage, only for decoupling internal regulators
7. 10-bit ADC does not have dedicated reference and its reference is double bonded to 10-bit ADC supply(VDD\_HV\_ADC0).
8. T<sub>j</sub>=150°C. Assumes T<sub>a</sub>=125°C
  - Assumes maximum θJA. See [Thermal attributes](#)

## 2.3 Recommended operating conditions

### NOTE

- For normal device operations, all supplies must be within operating range corresponding to the range mentioned in following tables. This is required even if some of the features are not used.
- If VDD\_HV\_A is in 3.3V range, VDD\_HV\_FL A should be externally supplied using a 3.3V source. If VDD\_HV\_A is in 3.3V range, VDD\_HV\_FL A should be shorted to VDD\_HV\_A.

**Table 2. Recommended operating conditions (V<sub>DD\_HV\_x</sub> = 3.3 V)**

| Symbol                                                                                                      | Parameter                                         | Conditions | Min <sup>1</sup> | Max              | Unit |
|-------------------------------------------------------------------------------------------------------------|---------------------------------------------------|------------|------------------|------------------|------|
| V <sub>DD_HV_A</sub> <sup>2</sup><br>V <sub>DD_HV_B</sub> <sup>2</sup><br>V <sub>DD_HV_C</sub> <sup>2</sup> | 3.3 V input/output supply voltage                 | —          | 3.15             | 3.6              | V    |
| V <sub>SS_HV</sub>                                                                                          | Input/output ground voltage                       | —          | 0                | 0                | V    |
| V <sub>DD_HV_FL A</sub> <sup>3</sup>                                                                        | 3.3 V flash supply voltage (generated internally) | —          | 3.15             | 3.6              | V    |
| V <sub>DD_HV_ADC1_REF</sub>                                                                                 | 3.3 V / 5.0 V ADC1 high reference voltage         | —          | 3.0              | 5.5              | V    |
| V <sub>DD_HV_ADC0</sub><br>V <sub>DD_HV_ADC1</sub>                                                          | 3.3 V ADC supply voltage                          | —          | 3.15             | 3.6 <sup>4</sup> | V    |

Table continues on the next page...

**Table 2. Recommended operating conditions ( $V_{DD\_HV\_x} = 3.3\text{ V}$ ) (continued)**

| Symbol                                   | Parameter                                                   | Conditions                    | Min <sup>1</sup> | Max              | Unit |
|------------------------------------------|-------------------------------------------------------------|-------------------------------|------------------|------------------|------|
| $V_{SS\_HV\_ADC0}$<br>$V_{SS\_HV\_ADC1}$ | 3.3 V ADC supply ground                                     | —                             | 0                | 0                | V    |
| $V_{DD\_LV}$ <sup>5</sup>                | Internal supply voltage                                     | —                             | 1.2              | 1.32             | V    |
| $V_{IN1\_CMP\_REF}$ <sup>5, 6, 7</sup>   | Analog Comparator DAC reference voltage                     | —                             | 3.15             | 3.6 <sup>6</sup> | V    |
| $V_{SS\_LV}$                             | Internal reference voltage                                  | —                             | 0                | 0                | V    |
| $I_{INJPAD}$                             | Injected input current on any pin during overload condition | —                             | -3.0             | 3.0              | mA   |
| $T_A$ <sup>8</sup>                       | Ambient temperature under bias                              | $f_{CPU} \leq 160\text{ MHz}$ | -40              | 125              | °C   |
| $T_J$                                    | Junction temperature under bias                             | —                             | -40              | 150              | °C   |

- Device will be functional down (and electrical specifications as per various datasheet parameters will be guaranteed) to the point where the LVD\_IO\_A\_LO resets the device. When voltage drops below VLVD\_IO\_A\_LO, device is reset.
- $V_{DD\_HV\_A}$ ,  $V_{DD\_HV\_B}$  and  $V_{DD\_HV\_C}$  are all independent supplies and can each be set to 3.3V or 5V. For example, if  $V_{DD\_HV\_A} = 5V$ , then  $V_{DD\_HV\_B}$  and  $V_{DD\_HV\_C}$  can both be 3.3V. However, care must be taken over ADC inputs that operate across the IO segments (Subject to Note 1).
- $V_{DD\_HV\_FLA}$  must be connected to  $V_{DD\_HV\_A}$  when  $V_{DD\_HV\_A} = 3.3V$
- PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from  $V_{DD\_HV\_B}$  domain hence  $V_{DD\_HV\_ADC1}$  should be within  $\pm 100\text{ mV}$  of  $V_{DD\_HV\_B}$  when these channels are used for ADC\_1.
- Only applicable when supplying from external source.
- $V_{IN1\_CMP\_REF} \leq V_{DD\_HV\_A}$
- This supply is shorted  $V_{DD\_HV\_A}$  on lower packages.
- $T_J = 150^\circ\text{C}$ . Assumes  $T_A = 125^\circ\text{C}$ 
  - Assumes maximum  $\theta_{JA}$ . See [Thermal attributes](#)

**NOTE**

- If  $V_{DD\_HV\_A}$  is in 5V range, it is necessary to use internal Flash supply 3.3V regulator.  $V_{DD\_HV\_FLA}$  should not be supplied externally and should only have decoupling capacitor.

**Table 3. Recommended operating conditions ( $V_{DD\_HV\_x} = 5\text{ V}$ )**

| Symbol                                                                                       | Parameter                                 | Conditions | Min <sup>1</sup> | Max | Unit |
|----------------------------------------------------------------------------------------------|-------------------------------------------|------------|------------------|-----|------|
| $V_{DD\_HV\_A}$ <sup>2</sup><br>$V_{DD\_HV\_B}$ <sup>2</sup><br>$V_{DD\_HV\_C}$ <sup>2</sup> | 5.0 V input/output supply voltage         | —          | 4.5              | 5.5 | V    |
| $V_{SS\_HV}$                                                                                 | Input/output ground voltage               | —          | 0                | 0   | V    |
| $V_{DD\_HV\_FLA}$ <sup>3</sup>                                                               | 3.3 V flash supply voltage                | —          | 3.15             | 3.6 | V    |
| $V_{DD\_HV\_ADC1\_REF}$                                                                      | 3.3 V / 5.0 V ADC1 high reference voltage | —          | 3.0              | 5.5 | V    |
| $V_{DD\_HV\_ADC0}$<br>$V_{DD\_HV\_ADC1}$                                                     | 3.3 V / 5.0 V ADC supply voltage          | —          | 3.0              | 5.5 | V    |
| $V_{SS\_HV\_ADC0}$<br>$V_{SS\_HV\_ADC1}$                                                     | 5.0 V ADC supply ground                   | —          | 0                | 0   | V    |

Table continues on the next page...

**Table 3. Recommended operating conditions ( $V_{DD\_HV\_x} = 5\text{ V}$ ) (continued)**

| Symbol                    | Parameter                                                   | Conditions                    | Min <sup>1</sup> | Max  | Unit |
|---------------------------|-------------------------------------------------------------|-------------------------------|------------------|------|------|
| $V_{DD\_LV}$ <sup>4</sup> | Internal supply voltage                                     | —                             | 1.2              | 1.32 | V    |
| $V_{SS\_LV}$              | Internal reference voltage                                  | —                             | 0                | 0    | V    |
| $I_{INJPAD}$              | Injected input current on any pin during overload condition | —                             | -3.0             | 3.0  | mA   |
| $T_A$ <sup>5</sup>        | Ambient temperature under bias                              | $f_{CPU} \leq 160\text{ MHz}$ | -40              | 125  | °C   |
| $T_J$                     | Junction temperature under bias                             | —                             | -40              | 150  | °C   |

1. Device will be functional down (and electrical specifications as per various datasheet parameters will be guaranteed) to the point where the LVD\_IO\_A\_LO resets the device. When voltage drops below VLVD\_IO\_A\_LO, device is reset.
2. VDD\_HV\_A, VDD\_HV\_B and VDD\_HV\_C are all independent supplies and can each be set to 3.3V or 5V. For example, if VDD\_HV\_A = 5V, then VDD\_HV\_B and VDD\_HV\_C can both be 3.3V. However, care must be taken over ADC inputs that operate across the IO segments.
3. When VDD\_HV is in 5 V range, VDD\_HV\_FL A cannot be supplied externally. This pin is decoupled with  $C_{flash\_reg}$ .
4. PA3, PA7, PA10, PA11 and PE12 ADC\_1 channels are coming from VDD\_HV\_B domain hence VDD\_HV\_ADC1 should be within  $\pm 100\text{ mV}$  of VDD\_HV\_B when these channels are used for ADC\_1.
5.  $T_J = 150^\circ\text{C}$ . Assumes  $T_A = 125^\circ\text{C}$ 
  - Assumes maximum  $\theta_{JA}$ . See [Thermal attributes](#)

## 2.4 Voltage regulator electrical characteristics

The voltage regulator is composed of the following blocks:

- Choice of generating supply voltage for the core area.
  - Control of external NPN ballast transistor
  - Connecting an external 1.25V (nominal) directly without the NPN ballast
- Internal generation of the 3.3V flash supply when device connected in 5V applications
- External bypass of the 3.3V flash regulator when device connected in 3.3V applications
- Low voltage detector - low range (LVD\_IO\_A\_LO) for 3.3 V to 5V supply to IO ( $V_{DD\_HV\_A}$ )
- Low voltage detector - high range (LVD\_IO\_A\_Hi) for the 3.3 V to 5V supply ( $V_{DD\_HV\_A}$ )
- Low voltage detector (LVD\_FLASH) for 3.3 V flash supply ( $V_{DD\_HV\_FLA}$ )
- Various low voltage detectors (LVD\_LV\_x) for 1.2 V digital core supply ( $V_{DD\_LV}$ )
- High voltage detector (HVD\_LV\_cold) for 1.2 V digital core supply ( $V_{DD\_LV}$ )
- Power on Reset (POR\_LV) for 1.25 V digital core supply ( $V_{DD\_LV}$ )
- Power on Reset (POR\_HV) for 3.3V to 5V supply ( $V_{DD\_HV\_A}$ )

The following bipolar transistors<sup>1</sup> are supported, depending on the device performance requirements. As a minimum the following must be considered when determining the most appropriate solution to maintain the device under its maximum power dissipation capability: current, ambient temperature, mounting pad area, duty cycle and frequency for  $I_{dd}$ , collector voltage, etc

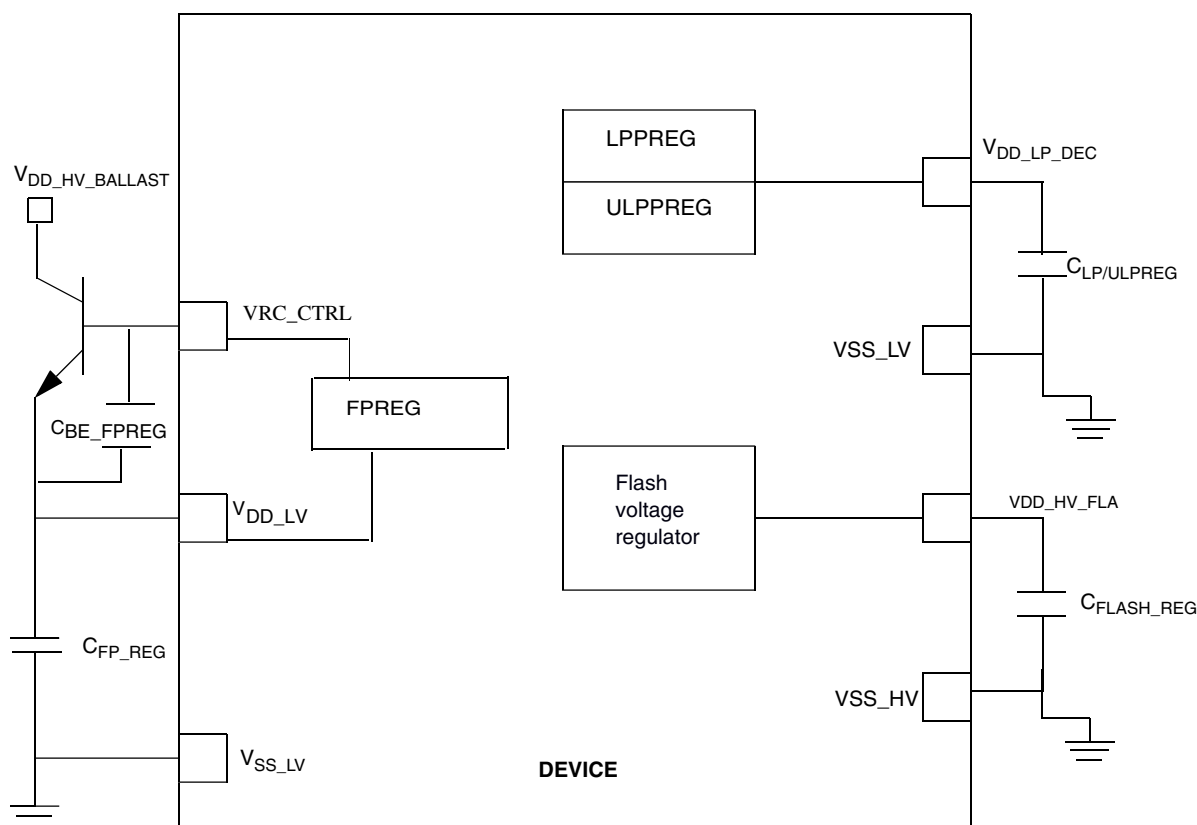


**Figure 1. Voltage regulator capacitance connection**

**Table 4. Voltage regulator electrical specifications**

| Symbol                     | Parameter                                                                   | Conditions                                                                                              | Min   | Typ              | Max  | Unit    |
|----------------------------|-----------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------|-------|------------------|------|---------|
| $C_{fp\_reg}$ <sup>1</sup> | External decoupling / stability capacitor                                   | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations. | 1.32  | 2.2 <sup>2</sup> | 3    | $\mu F$ |
|                            | Combined ESR of external capacitor                                          | —                                                                                                       | 0.001 | —                | 0.03 | Ohm     |
| $C_{lp/ulp\_reg}$          | External decoupling / stability capacitor for internal low power regulators | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations. | 0.8   | 1                | 1.4  | $\mu F$ |
|                            | Combined ESR of external capacitor                                          | —                                                                                                       | 0.001 | —                | 0.1  | Ohm     |

*Table continues on the next page...*

1. These are guaranteed ballasts.

**Table 4. Voltage regulator electrical specifications (continued)**

| Symbol                           | Parameter                                                               | Conditions                                                                                                                                                                                         | Min   | Typ | Max  | Unit    |
|----------------------------------|-------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|-----|------|---------|
| $C_{be\_freg}$                   | Capacitor in parallel to base-emitter                                   | BCP68 and BCP56                                                                                                                                                                                    |       | 3.3 |      | nF      |
|                                  |                                                                         | MJD31                                                                                                                                                                                              |       | 4.7 |      |         |
| $C_{flash\_reg}$ <sup>3</sup>    | External decoupling / stability capacitor for internal Flash regulators | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.                                                                                            | 1.32  | 2.2 | 3    | $\mu F$ |
|                                  | Combined ESR of external capacitor                                      | —                                                                                                                                                                                                  | 0.001 | —   | 0.03 | Ohm     |
| $C_{HV\_VDD\_A}$                 | VDD_HV_A supply capacitor                                               | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.                                                                                            | 1     | —   | —    | $\mu F$ |
| $C_{HV\_ADC0}$<br>$C_{HV\_ADC1}$ | HV ADC supply decoupling capacitances                                   | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.                                                                                            | 1     | —   | —    | $\mu F$ |
| $C_{HV\_ADR}$                    | HV ADC SAR reference supply decoupling capacitances                     | Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.                                                                                            | 0.47  | —   | —    | $\mu F$ |
| $V_{DD\_HV\_BALLAST}$            | FPREG Ballast collector supply voltage                                  | When collector of NPN ballast is directly supplied by an on board supply source (not shared with VDD_HV_A supply pin) without any series resistance, that is, $R_{C\_BALLAST}$ less than 0.01 Ohm. | 2.25  | —   | 5.5  | V       |
| $R_{C\_BALLAST}$                 | Series resistor on collector of FPREG ballast                           | When VDD_HV_BALLAST is shorted to VDD_HV_A on the board                                                                                                                                            | —     | —   | 0.1  | Ohm     |
| $t_{SU}$                         | Start-up time after main supply stabilization                           | $C_{fp\_reg} = 3 \mu F$                                                                                                                                                                            | —     | 74  | —    | $\mu s$ |
| $t_{ramp}$                       | Load current transient                                                  | Iload from 15% to 55%<br>$C_{fp\_reg} = 3 \mu F$                                                                                                                                                   |       | 1.0 |      | $\mu s$ |

1. Split capacitance on each pair VDD\_LV pin should sum up to a total value of  $C_{fp\_reg}$
2. Typical values will vary over temperature, voltage, tolerance, drift, but total variation must not exceed minimum and maximum values.
3. It is required to minimize the board parasitic inductance from decoupling capacitor to VDD\_HV\_FL A pin and the routing inductance should be less than 1nH.

## 2.5 Voltage monitor electrical characteristics

Table 5. Voltage monitor electrical characteristics

| Symbol                                | Parameter                                                                       | State | Conditions | Configuration         |                         |            | Threshold         |       |       | Unit |
|---------------------------------------|---------------------------------------------------------------------------------|-------|------------|-----------------------|-------------------------|------------|-------------------|-------|-------|------|
|                                       |                                                                                 |       |            | Power Up <sup>1</sup> | Mask Opt <sup>2,2</sup> | Reset Type | Min               | Typ   | Max   | V    |
| V <sub>POR_LV</sub>                   | LV supply power on reset detector                                               | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 0.930             | 0.979 | 1.028 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 0.959             | 0.979 | 0.999 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 0.980             | 1.029 | 1.078 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.009             | 1.029 | 1.049 | V    |
| V <sub>HVD_LV_cold</sub>              | LV external supply high voltage monitoring, detecting at the device pin         | Fall  | Untrimmed  | No                    | Yes                     | Functional | Disabled at Start |       |       |      |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.330             | 1.345 | 1.360 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | Disabled at Start |       |       |      |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.350             | 1.365 | 1.380 | V    |
| V <sub>LVD_LV_PD2_hot</sub>           | LV internal supply low voltage monitoring, detecting in the PD2 core (hot) area | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 1.080             | 1.120 | 1.160 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.130             | 1.145 | 1.160 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 1.100             | 1.140 | 1.180 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.150             | 1.165 | 1.180 | V    |
| V <sub>LVD_LV_PD1_hot</sub>           | LV internal supply low voltage monitoring, detecting in the PD1 core (hot) area | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 1.080             | 1.120 | 1.160 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.114             | 1.137 | 1.160 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 1.100             | 1.140 | 1.180 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.134             | 1.157 | 1.180 | V    |
| V <sub>LVD_LV_PD0_hot</sub>           | LV internal supply low voltage monitoring, detecting in the PD0 core (hot) area | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 1.080             | 1.120 | 1.160 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.114             | 1.137 | 1.160 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 1.100             | 1.140 | 1.180 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 1.134             | 1.157 | 1.180 | V    |
| V <sub>POR_HV</sub>                   | HV supply power on reset detector                                               | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 2.700             | 2.850 | 3.000 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 2.815             | 2.873 | 2.930 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 2.750             | 2.900 | 3.050 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 2.845             | 2.903 | 2.960 | V    |
| V <sub>LVD_IO_A_LO</sub> <sup>3</sup> | HV IO_A supply low voltage monitoring - low range                               | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 2.750             | 2.923 | 3.095 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 2.978             | 3.039 | 3.100 | V    |
|                                       |                                                                                 | Rise  | Untrimmed  |                       |                         |            | 2.780             | 2.953 | 3.125 | V    |
|                                       |                                                                                 |       | Trimmed    |                       |                         |            | 3.008             | 3.069 | 3.130 | V    |

Table continues on the next page...

**Table 5. Voltage monitor electrical characteristics (continued)**

| Symbol                                                                            | Parameter                                                              | State | Conditions | Configuration         |                         |            | Threshold         |       |       | Unit |
|-----------------------------------------------------------------------------------|------------------------------------------------------------------------|-------|------------|-----------------------|-------------------------|------------|-------------------|-------|-------|------|
|                                                                                   |                                                                        |       |            | Power Up <sup>1</sup> | Mask Opt <sup>2,2</sup> | Reset Type | Min               | Typ   | Max   | V    |
| V <sub>LVD_IO_A_HI</sub> <sup>3</sup>                                             | HV IO_A supply low voltage monitoring - high range                     | Fall  | Trimmed    | No                    | Yes                     | Functional | Disabled at Start |       |       |      |
|                                                                                   |                                                                        |       |            |                       |                         |            | 4.068             | 4.151 | 4.234 | V    |
|                                                                                   |                                                                        | Rise  | Trimmed    |                       |                         |            | Disabled at Start |       |       |      |
|                                                                                   |                                                                        |       |            |                       |                         |            | 4.118             | 4.201 | 4.284 | V    |
| V <sub>LVD_FLASH</sub>                                                            | Flash supply low voltage monitoring                                    | Fall  | Untrimmed  | Yes                   | No                      | Powerup    | 2.898             | 3.004 | 3.110 | V    |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 2.900             | 2.930 | 2.960 | V    |
|                                                                                   |                                                                        | Rise  | Untrimmed  |                       |                         |            | 2.918             | 3.024 | 3.130 | V    |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 2.920             | 2.950 | 2.980 | V    |
|                                                                                   |                                                                        |       |            |                       |                         |            |                   |       |       |      |
| V <sub>LVD_FLASH</sub> during low power mode using LPBG as reference <sup>4</sup> |                                                                        | Fall  | Untrimmed  |                       |                         |            | Disable           |       |       |      |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 2.650             | 2.704 | 2.758 | V    |
|                                                                                   |                                                                        | Rise  | Untrimmed  |                       |                         |            | Disable           |       |       |      |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 2.670             | 2.724 | 2.778 | V    |
|                                                                                   |                                                                        |       |            |                       |                         |            |                   |       |       |      |
| V <sub>LVD_LV_PD2_cold</sub>                                                      | LV internal supply low voltage monitoring, detecting at the device pin | Fall  | Untrimmed  | No                    | Yes                     | Functional | Disabled at Start |       |       |      |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 1.145             | 1.160 | 1.175 | V    |
|                                                                                   |                                                                        | Rise  | Untrimmed  |                       |                         |            | Disabled at Start |       |       |      |
|                                                                                   |                                                                        |       | Trimmed    |                       |                         |            | 1.165             | 1.180 | 1.195 | V    |
|                                                                                   |                                                                        |       |            |                       |                         |            |                   |       |       |      |

1. All monitors that are active at power-up will gate the power up recovery and prevent exit from POWERUP phase until the minimum level is crossed. These monitors can in some cases be masked during normal device operation, but when active will always generate a destructive reset.
2. Voltage monitors marked as non maskable are essential for device operation and hence cannot be masked.
3. There is no voltage monitoring on the VDD\_HV\_B and VDD\_HV\_C I/O segments. For applications requiring monitoring of these segments, either connect these to VDD\_HV\_A at the pcb level or monitor externally.
4. LVD\_FLASH is active in low power modes to ensure that VDD\_HV\_FLA does not drop below 2.5V, so that Flash can exit from low power mode upon wakeup.

## 2.6 Supply current characteristics

Current consumption data is given in the following table. These specifications are design targets and are subject to change per device characterization.

**NOTE**

The ballast must be chosen in accordance with the ballast transistor supplier operating conditions and recommendations.

**Table 6. Current consumption characteristics**

| Symbol                         | Parameter                                     | Conditions <sup>1</sup>                                                                                                                                          | Min | Typ | Max | Unit |
|--------------------------------|-----------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| I <sub>DD_FULL</sub><br>2, 3   | RUN Full Mode<br>Operating current            | LV supply + HV supply + HV Flash supply +<br>2 x HV ADC supplies<br>T <sub>a</sub> = 85°C<br>V <sub>DD_LV</sub> = 1.25 V<br>VDD_HV_A = 5.5V<br>SYS_CLK = 160MHz  | —   | 310 | 520 | mA   |
|                                |                                               | T <sub>a</sub> = 105°C                                                                                                                                           | —   | —   | 540 | mA   |
|                                |                                               | T <sub>a</sub> = 125 °C <sup>4</sup>                                                                                                                             | —   | —   | 575 | mA   |
|                                |                                               |                                                                                                                                                                  |     |     |     |      |
| I <sub>DD_GWY</sub><br>5, 6    | RUN Gateway<br>Mode Operating<br>current      | LV supply + HV supply + HV Flash supply + 2 x HV<br>ADC supplies<br>T <sub>a</sub> = 85°C<br>V <sub>DD_LV</sub> = 1.25 V<br>VDD_HV_A = 5.5V<br>SYS_CLK = 160MHz  | —   | —   | 460 | mA   |
|                                |                                               | T <sub>a</sub> = 105°C                                                                                                                                           | —   | —   | 486 | mA   |
|                                |                                               | T <sub>a</sub> = 125°C <sup>4</sup>                                                                                                                              | —   | —   | 521 | mA   |
|                                |                                               |                                                                                                                                                                  |     |     |     |      |
| I <sub>DD_BODY_1</sub><br>7, 8 | RUN Body Mode<br>Profile Operating<br>current | LV supply + HV supply + HV Flash supply + 2 x HV<br>ADC supplies<br>T <sub>a</sub> = 85 °C<br>V <sub>DD_LV</sub> = 1.25 V<br>VDD_HV_A = 5.5V<br>SYS_CLK = 120MHz | —   | —   | 345 | mA   |
|                                |                                               | T <sub>a</sub> = 105 °C                                                                                                                                          | —   | —   | 370 | mA   |
|                                |                                               | T <sub>a</sub> = 125°C <sup>4</sup>                                                                                                                              | —   | —   | 405 | mA   |
|                                |                                               |                                                                                                                                                                  |     |     |     |      |
| IDD_BODY_2 <sup>9, 10</sup>    | RUN Body Mode<br>Profile Operating<br>current | LV supply + HV supply + HV Flash supply + 2 x HV<br>ADC supplies<br>T <sub>a</sub> = 85 °C<br>V <sub>DD_LV</sub> = 1.25 V<br>VDD_HV_A = 5.5V<br>SYS_CLK = 80MHz  | —   | —   | 275 | mA   |
|                                |                                               | T <sub>a</sub> = 105 °C                                                                                                                                          | —   | —   | 300 | mA   |
|                                |                                               | T <sub>a</sub> = 125 °C <sup>4</sup>                                                                                                                             | —   | —   | 336 | mA   |
|                                |                                               |                                                                                                                                                                  |     |     |     |      |

Table continues on the next page...

**Table 6. Current consumption characteristics (continued)**

| Symbol                                   | Parameter                                        | Conditions <sup>1</sup>                                                                                                 | Min | Typ | Max | Unit          |
|------------------------------------------|--------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| $I_{DD\_STOP}$                           | STOP mode<br>Operating current                   | $T_a = 25\text{ }^{\circ}\text{C}$<br>$V_{DD\_LV} = 1.25\text{ V}$                                                      | —   | 11  | —   | mA            |
|                                          |                                                  | $T_a = 55\text{ }^{\circ}\text{C}$<br>$V_{DD\_LV} = 1.25\text{ V}$                                                      | —   | —   | TBD |               |
|                                          |                                                  | $T_a = 125\text{ }^{\circ}\text{C}$ <sup>4</sup><br>$V_{DD\_LV} = 1.25\text{ V}$                                        | —   | —   | 160 |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
| $I_{DD\_HALT}$                           | HALT mode<br>Operating current                   | $T_a = 25\text{ }^{\circ}\text{C}$<br>$V_{DD\_LV} = 1.25\text{ V}$                                                      | —   | —   | TBD | mA            |
|                                          |                                                  | $T_a = 55\text{ }^{\circ}\text{C}$<br>$V_{DD\_LV} = 1.25\text{ V}$                                                      | —   | —   | TBD |               |
|                                          |                                                  | $T_a = 125\text{ }^{\circ}\text{C}$ <sup>4</sup><br>$V_{DD\_LV} = 1.25\text{ V}$                                        | —   | —   | TBD |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
| $I_{DD\_HV\_ADC\_REF}$ <sup>11, 12</sup> | ADC REF<br>Operating current                     | $T_a = 25\text{ }^{\circ}\text{C}$<br>2 ADCs operating at 80 MHz<br>$V_{DD\_HV\_ADC\_REF} = 3.6\text{ V}$               | —   | 200 | 400 | $\mu\text{A}$ |
|                                          |                                                  | $T_a = 125\text{ }^{\circ}\text{C}$ <sup>4</sup><br>2 ADCs operating at 80 MHz<br>$V_{DD\_HV\_ADC\_REF} = 5.5\text{ V}$ | —   | 200 | 400 |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
| $I_{DD\_HV\_ADCx}$ <sup>12</sup>         | ADC HV<br>Operating current                      | $T_a = 25\text{ }^{\circ}\text{C}$<br>ADC operating at 80 MHz<br>$V_{DD\_HV\_ADC} = 3.6\text{ V}$                       | —   | 1   | 2   | mA            |
|                                          |                                                  | $T_a = 125\text{ }^{\circ}\text{C}$ <sup>4</sup><br>ADC operating at 80 MHz<br>$V_{DD\_HV\_ADC} = 5.5\text{ V}$         | —   | 1.2 | 2   |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
|                                          |                                                  |                                                                                                                         |     |     |     |               |
| $I_{DD\_HV\_FLASH}$                      | Flash Operating<br>current during<br>read access | $T_a = 125\text{ }^{\circ}\text{C}$ <sup>4</sup><br>3.3 V supplies<br>x MHz frequency                                   | —   | 40  | 45  | mA            |

1. The content of the Conditions column identifies the components that draw the specific current.
2. ALL Modules enabled at maximum frequency: 2 x e200Z4 @160 MHz, e200Z2 at 80 MHz, Platform @160MHz, DMA (SRAM to SRAM), all SRAMs accessed in parallel, Flash access(prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals (500 pll clock cycles), ENET0 transmitting, MLB transmitting, FlexRay transmitting, USB-SPH transmitting (USB-OTG only clocked), 2 x I2C transmitting (rest clocked), 1 x SAI transmitting (rest clocked), ADC0 converting using BCTU triggers triggered through PIT (other ADC clocked), RTC running, 3 x STM running, 2 x DSPI transmitting (rest clocked), 2 x SPI transmitting (rest clocked), 4 x CAN state machines working(rest clocked), 9 x LINFLEX transmitting (rest clocked), 1 x EMIOs clocked (used OPWFMB mode) (Others clock gated), SDHC, 3 x CMP only clocked, FIRC, SIRC, FXOSC, SXOSC, PLL running. All others modules clock gated if not specifically mentioned. I/O supply current excluded.
3. Recommended Transistors:MJD31 @ 85°C, 105°C and 125°C.
4.  $T_j=150^{\circ}\text{C}$ . Assumes  $T_a=125^{\circ}\text{C}$ 
  - Assumes maximum  $\theta_{JA}$ . See [Thermal attributes](#)
5. Enabled Modules in Gateway mode: 2 x e200Z4 @160 MHz (Instruction and Data cache enabled), Platform @160MHz, e200Z2 at 80 MHz(Instruction cache enabled), all SRAMs accessed in parallel, Flash access(prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals(500 pll clock cycles), ENET0 transmitting, MLB

- transmitting, FlexRay transmitting, USB-SPH Transmitting, USB-OTG clocked, 2 x I2C transmitting, (2 x I2C clock gated), 1 x SAI transmitting (2 x SAI clock gated), ADC0 converting in continuous mode (ADC1 clock gated), PIT clocked, RTC clocked, 3 x STM clocked, 2 x DSPI transmitting (Other DSPS clock gated), 2 x SPI transmitting (Other SPIs clock gated), 4 x FlexCAN state machines clocked (other FLEXCAN clock gated), 4 x LINFLEX transmitting (Other clock gated), 1x EMIOs clocked (used OPWFMB mode) (Others clock gated), FIRC, SIRC, FXOSC, SXOSC, PLL running, BCTU, DMA\_CH\_MUX, ACMP clock gated. All others modules clock gated if not specifically mentioned. I/O supply current excluded
6. Recommended Transistors: MJD31 @ 85°C, 105°C and 125°C.
  7. Enabled Modules in Body mode enabled at maximum frequency: 2 x e200Z4 @ 120Mhz (Instruction and Data cache enabled), Platform @ 120MHz, SRAMs accessed in parallel, Flash access (prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals (500 pll clock cycles), DMA (SRAM to SRAM), ADC0 converting using BCTU triggers which are triggered through PIT (ADC1 clocked), RTC clocked, 3 x STM clocked, 2 x DSPI transmitting (others DSPIs clocked), 2 x SPI transmitting (others clocked), 4 x FlexCAN state machines working (others clocked), 9x LINFLEX transmitting (others clocked), 1x EMIOs operational (used OPWFMB mode) (others clocked), FIRC, SIRC, FXOSC, SXOSC, PLL running, MEMU, FCCU, SIUL, SDHC, CMP clocked, e200Z2, ENET, MLB, SAI, I2C, FlexRay, USB clock gated. All others modules clock gated if not specifically mentioned I/O supply current excluded
  8. Recommended Transistors: BCP56, BCP68 or MJD31 @ 85°C, BCP56, BCP68 or MJD31 @ 105°C and MJD31 @ 125°C.
  9. Enabled Modules in Body mode enabled at maximum frequency: 2 x e200Z4 @ 80Mhz (Instruction and Data cache enabled), Platform @ 80MHz, SRAMs accessed in parallel, Flash access (prefetch is disabled while buffers are enabled), HSM reading from flash at regular intervals (500 pll clock cycles), DMA (SRAM to SRAM), ADC0 converting using BCTU triggers which are triggered through PIT (ADC1 clocked), RTC clocked, 3 x STM clocked, 2 x DSPI transmitting (others DSPIs clocked), 2 x SPI transmitting (others clocked), 4 x FlexCAN state machines working (others clocked), 9x LINFLEX transmitting (others clocked), 1x EMIOs operational (used OPWFMB mode) (others clocked), FIRC, SIRC, FXOSC, SXOSC, PLL running, MEMU, FCCU, SIUL, SDHC, CMP clocked, e200Z2, ENET, MLB, SAI, I2C, FlexRay, USB clock gated. All others modules clock gated if not specifically mentioned I/O supply current excluded
  10. Recommended Transistors: BCP56, BCP68 or MJD31 @ 85°C, 105°C and 125°C
  11. Internal structures hold the input voltage less than  $V_{DD\_HV\_ADC\_REF} + 1.0$  V on all pads powered by  $V_{DDA}$  supplies, if the maximum injection current specification is met (3 mA for all pins) and  $V_{DDA}$  is within the operating voltage specifications.
  12. This value is the total current for two ADCs. Each ADC might consume up to 2mA at max.

**Table 7. Low Power Unit (LPU) Current consumption characteristics**

| Symbol   | Parameter                                      | Conditions <sup>1</sup>                                                                       | Min | Typ  | Max  | Unit |
|----------|------------------------------------------------|-----------------------------------------------------------------------------------------------|-----|------|------|------|
| LPU_RUN  | with 256K RAM, but only one RAM being accessed | $T_a = 25^\circ\text{C}$<br>SYS_CLK = 16MHz<br>ADC0 = OFF, SPI0 = OFF, LIN0 = OFF, CAN0 = OFF | —   | 10   |      | mA   |
|          |                                                | $T_a = 125^\circ\text{C}$<br>SYS_CLK = 16MHz<br>ADC0 = ON, SPI0 = ON, LIN0 = ON, CAN0 = ON    | —   |      | 26   |      |
| LPU_STOP | with 256K RAM                                  | $T_a = 25^\circ\text{C}$                                                                      | —   | 0.15 | —    | mA   |
|          |                                                | $T_a = 125^\circ\text{C}$                                                                     | —   |      | 10.6 |      |

1. The content of the Conditions column identifies the components that draw the specific current.

**Table 8. STANDBY Current consumption characteristics**

| Symbol   | Parameter             | Conditions <sup>1</sup>   | Min | Typ  | Max  | Unit          |
|----------|-----------------------|---------------------------|-----|------|------|---------------|
| STANDBY0 | STANDBY with 8K RAM   | $T_a = 25^\circ\text{C}$  | —   | 45   | —    | $\mu\text{A}$ |
|          |                       | $T_a = 125^\circ\text{C}$ | —   |      | 2400 |               |
| STANDBY1 | STANDBY with 64K RAM  | $T_a = 25^\circ\text{C}$  | —   | 46.5 | —    | $\mu\text{A}$ |
|          |                       | $T_a = 125^\circ\text{C}$ | —   |      | 3000 |               |
| STANDBY2 | STANDBY with 128K RAM | $T_a = 25^\circ\text{C}$  | —   | 48.1 | —    | $\mu\text{A}$ |
|          |                       | $T_a = 125^\circ\text{C}$ | —   |      | 3700 |               |

Table continues on the next page...

**Table 8. STANDBY Current consumption characteristics (continued)**

| Symbol   | Parameter             | Conditions <sup>1</sup> | Min | Typ  | Max  | Unit |
|----------|-----------------------|-------------------------|-----|------|------|------|
| STANDBY3 | STANDBY with 256K RAM | T <sub>a</sub> = 25 °C  | —   | 51.3 | —    | μA   |
|          |                       | T <sub>a</sub> = 125 °C | —   |      | 5100 |      |

1. The content of the Conditions column identifies the components that draw the specific current.

## 2.7 Electrostatic discharge (ESD) characteristics

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n + 1) supply pin). This test conforms to the AEC-Q100-002/-003/-011 standard.

### NOTE

A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing shall be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

**Table 9. ESD ratings**

| Symbol                | Parameter                                      | Conditions <sup>1</sup>                              | Class | Max value <sup>2</sup> | Unit |
|-----------------------|------------------------------------------------|------------------------------------------------------|-------|------------------------|------|
| V <sub>ESD(HBM)</sub> | Electrostatic discharge (Human Body Model)     | T <sub>A</sub> = 25 °C<br>conforming to AEC-Q100-002 | H1C   | 2000                   | V    |
| V <sub>ESD(CDM)</sub> | Electrostatic discharge (Charged Device Model) | T <sub>A</sub> = 25 °C<br>conforming to AEC-Q100-011 | C3A   | 500<br>750 (corners)   | V    |

1. All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.
2. Data based on characterization results, not tested in production.

## 2.8 Electromagnetic Compatibility (EMC) specifications

EMC measurements to IC-level IEC standards are available from Freescale on request.

### 3 I/O parameters

#### 3.1 AC specifications @ 3.3 V Range

Table 10. Functional Pad AC Specifications @ 3.3 V Range

| Symbol                                     | Prop. Delay (ns) <sup>1</sup><br>L>H/H>L |           | Rise/Fall Edge (ns) |         | Drive Load (pF)        | ipp_sre[1:0]    |
|--------------------------------------------|------------------------------------------|-----------|---------------------|---------|------------------------|-----------------|
|                                            | Min                                      | Max       | Min                 | Max     |                        | MSB,LSB         |
| pad_sr_hv<br>(output)                      |                                          | 6/6       |                     | 1.5/1.5 | 25                     | 11              |
|                                            | 2.5/2.5                                  | 7.5/7.5   | 0.9/0.9             | 3/3     | 50                     |                 |
|                                            | 6.4/5                                    | 19.5/19.5 | 3.5/2.5             | 12/12   | 200                    |                 |
|                                            | 2.2/2.5                                  | 8/8       | 0.6/0.8             | 3.5/3.5 | 25                     | 10              |
|                                            | 0.090                                    | 1.1       | 0.035               | 1.1     | asymmetry <sup>2</sup> |                 |
|                                            | 2.9/3.5                                  | 11.5/11.5 | 1.8/1.2             | 6.5/6.5 | 50                     |                 |
|                                            | 11/8                                     | 35/31     | 7.7/5               | 25/21   | 200                    |                 |
|                                            | 8.3/9.6                                  | 45/45     | 4/3.5               | 25/25   | 50                     | 01 <sup>3</sup> |
|                                            | 13.5/15                                  | 65/65     | 6.3/6.2             | 30/30   | 200                    |                 |
|                                            | 13/13                                    | 75/75     | 6.8/6               | 40/40   | 50                     | 00 <sup>3</sup> |
|                                            | 21/22                                    | 100/100   | 11/11               | 51/51   | 200                    |                 |
| pad_i_hv/pad_sr_hv<br>(input) <sup>4</sup> |                                          | 2/2       |                     | 0.5/0.5 | 0.5                    | NA              |

1. As measured from 50% of core side input to Voh/Vol of the output

2. This row specifies the min and max asymmetry between both the prop delay and the edge rates for a given PVT and 25pF load. Required for the Flexray spec.

3. Slew rate control modes

4. Input slope = 2ns

#### NOTE

Data based on characterization results, not tested in production.

#### 3.2 DC electrical specifications @ 3.3V Range

Table 11. DC electrical specifications @ 3.3V Range

| Symbol                | Parameter                | Value |      | Unit |
|-----------------------|--------------------------|-------|------|------|
|                       |                          | Min   | Max  |      |
| dVdd <sup>1</sup>     | LV (core) Supply Voltage | 1.08  | 1.32 | V    |
| VDD_HV_x <sup>1</sup> | I/O Supply Voltage       | 2.97  | 3.63 | V    |

Table continues on the next page...

**Table 11. DC electrical specifications @ 3.3V Range (continued)**

| Symbol   | Parameter                                                 | Value              |                    | Unit |
|----------|-----------------------------------------------------------|--------------------|--------------------|------|
|          |                                                           | Min                | Max                |      |
| Vih      | CMOS Input Buffer High Voltage (with hysteresis disabled) | 0.55 *<br>VDD_HV_x | VDD_HV_x+<br>0.3   | V    |
| Vil      | CMOS Input Buffer Low Voltage (with hysteresis disabled)  | dVss - 0.3         | 0.40 *<br>VDD_HV_x | V    |
| Vhys     | CMOS Input Buffer Hysteresis                              | 0.1 *<br>VDD_HV_x  |                    | V    |
| Pull_loh | Weak Pullup Current <sup>2</sup>                          | 15                 | 50                 | μA   |
| Pull_lol | Weak Pulldown Current <sup>3</sup>                        | 15                 | 50                 | μA   |
| Iinact_d | Digital Pad Input Leakage Current (weak pull inactive)    | -2.5               | 2.5                | μA   |
| Voh      | Output High Voltage <sup>4</sup>                          | 0.8 *VDD_HV_x      | —                  | V    |
| Vol      | Output Low Voltage <sup>5</sup>                           | —                  | 0.2 *VDD_HV_x      | V    |
| Ioh_f    | Full drive Ioh <sup>6</sup> (ipp_sre[1:0] = 11)           | 18                 | 70                 | mA   |
| Iol_f    | Full drive Iol <sup>6</sup> (ipp_sre[1:0] = 11)           | 21                 | 120                | mA   |
| Ioh_h    | Half drive Ioh <sup>6</sup> (ipp_sre[1:0] = 10)           | 9                  | 35                 | mA   |
| Iol_h    | Half drive Iol <sup>6</sup> (ipp_sre[1:0] = 10)           | 10.5               | 60                 | mA   |

1. Max power supply ramp rate is 500 V / ms
2. Measured when pad = 0 V
3. Measured when pad = VDD\_HV\_x
4. Measured when pad is sourcing 2 mA
5. Measured when pad is sinking 2 mA
6. Ioh/Iol is derived from spice simulations. These values are NOT guaranteed by test.

### 3.3 AC specifications @ 5 V Range

**Table 12. Functional Pad AC Specifications @ 5 V Range**

| Symbol                | Prop. Delay (ns) <sup>1</sup><br>L>H/H>L |           | Rise/Fall Edge (ns) |         | Drive Load (pF) | ipp_sre[1:0]    |
|-----------------------|------------------------------------------|-----------|---------------------|---------|-----------------|-----------------|
|                       | Min                                      | Max       | Min                 | Max     |                 | MSB,LSB         |
| pad_sr_hv<br>(output) |                                          | 4.5/4.5   |                     | 1.2/1.2 | 25              | 11              |
|                       |                                          | 5.1/5.1   |                     | 2/2     | 50              |                 |
|                       |                                          | 13/13     |                     | 8/8     | 200             |                 |
|                       |                                          | 5.25/5.25 |                     | 2/2     | 25              |                 |
|                       |                                          | 8/8       |                     | 4/4     | 50              | 10              |
|                       |                                          | 22/22     |                     | 16/16   | 200             |                 |
|                       |                                          | 27/27     |                     | 12/12   | 50              |                 |
|                       |                                          | 40/40     |                     | 24/24   | 200             |                 |
|                       |                                          | 40/40     |                     | 24/24   | 50              | 01 <sup>2</sup> |
|                       |                                          | 65/65     |                     | 50/50   | 200             |                 |
|                       |                                          |           |                     |         |                 | 00 <sup>2</sup> |

Table continues on the next page...

**Table 12. Functional Pad AC Specifications @ 5 V Range (continued)**

| Symbol                        | Prop. Delay (ns) <sup>1</sup><br>L>H/H>L |         | Rise/Fall Edge (ns) |         | Drive Load (pF) | ipp_sre[1:0] |
|-------------------------------|------------------------------------------|---------|---------------------|---------|-----------------|--------------|
|                               | Min                                      | Max     | Min                 | Max     |                 | MSB,LSB      |
| pad_i_hv/pad_sr_hv<br>(input) |                                          | 1.5/1.5 |                     | 0.5/0.5 | 0.5             | NA           |

1. As measured from 50% of core side input to Voh/Vol of the output
2. Slew rate control modes

### 3.4 DC electrical specifications @ 5 V Range

**Table 13. DC electrical specifications @ 5 V Range**

| Symbol                | Parameter                                                 | Value              |                    | Unit |
|-----------------------|-----------------------------------------------------------|--------------------|--------------------|------|
|                       |                                                           | Min                | Max                |      |
| dVdd <sup>1</sup>     | LV (core) Supply Voltage                                  | 1.08               | 1.32               | V    |
| VDD_HV_x <sup>1</sup> | I/O Supply Voltage                                        | 4.5                | 5.5                | V    |
| Vih                   | CMOS Input Buffer High Voltage (with hysteresis disabled) | 0.55 *<br>VDD_HV_x | VDD_HV_x +<br>0.3  | V    |
| Vil                   | CMOS Input Buffer Low Voltage (with hysteresis disabled)  | dVss - 0.3         | 0.40 *<br>VDD_HV_x | V    |
| Vhys                  | CMOS Input Buffer Hysteresis                              | 0.1 *<br>VDD_HV_x  |                    | V    |
| Pull_loh              | Weak Pullup Current <sup>2</sup>                          | 30                 | 80                 | μA   |
| Pull_lol              | Weak Pulldown Current <sup>3</sup>                        | 30                 | 80                 | μA   |
| Iinact_d              | Digital Pad Input Leakage Current (weak pull inactive)    | -2.5               | 2.5                | μA   |
| Voh                   | Output High Voltage <sup>4</sup>                          | 0.8 *<br>VDD_HV_x  | —                  | V    |
| Vol                   | Output Low Voltage <sup>5</sup>                           | —                  | 0.2 *<br>VDD_HV_x  | V    |
| Ioh_f                 | Full drive Ioh <sup>6</sup> (ipp_sre[1:0] = 11)           | 38                 | 132                | mA   |
| Iol_f                 | Full drive Iol <sup>6</sup> (ipp_sre[1:0] = 11)           | 48                 | 220                | mA   |
| Ioh_h                 | Half drive Ioh <sup>6</sup> (ipp_sre[1:0] = 10)           | 19                 | 66                 | mA   |
| Iol_h                 | Half drive Iol <sup>6</sup> (ipp_sre[1:0] = 10)           | 24                 | 110                | mA   |

1. Max power supply ramp rate is 500 V / ms
2. Measured when pad = 0 V
3. Measured when pad = VDD\_HV\_x
4. Measured when pad is sourcing 2 mA
5. Measured when pad is sinking 2 mA
6. Ioh/Iol is derived from spice simulations. These values are NOT guaranteed by test.

### 3.5 Functional reset pad electrical specifications

The device implements a dedicated bidirectional RESET pin.

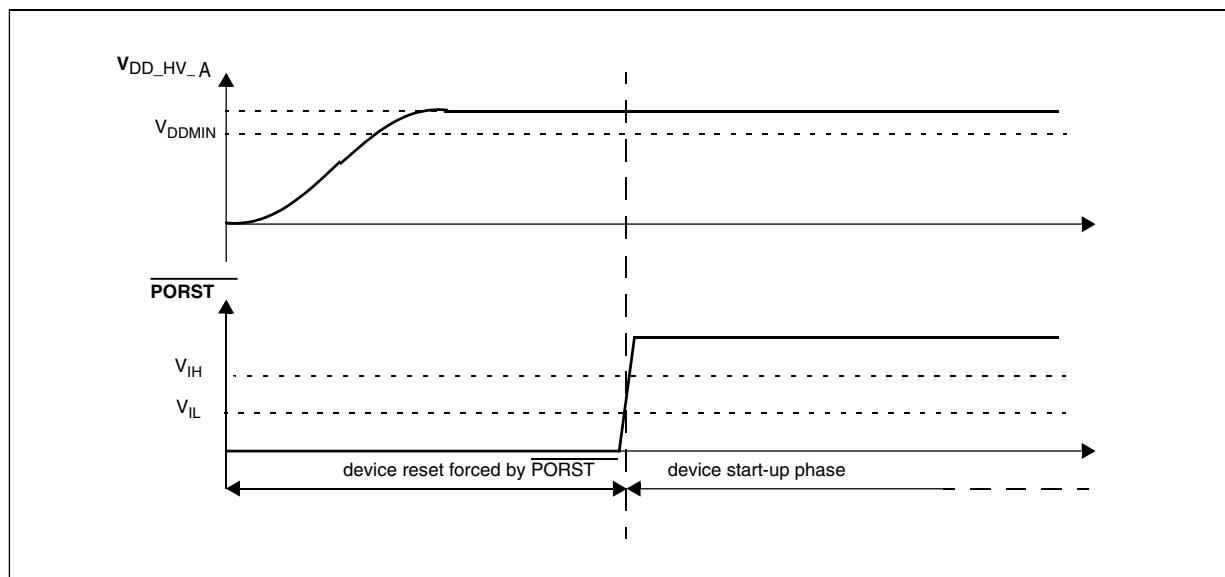


Figure 2. Start-up reset requirements

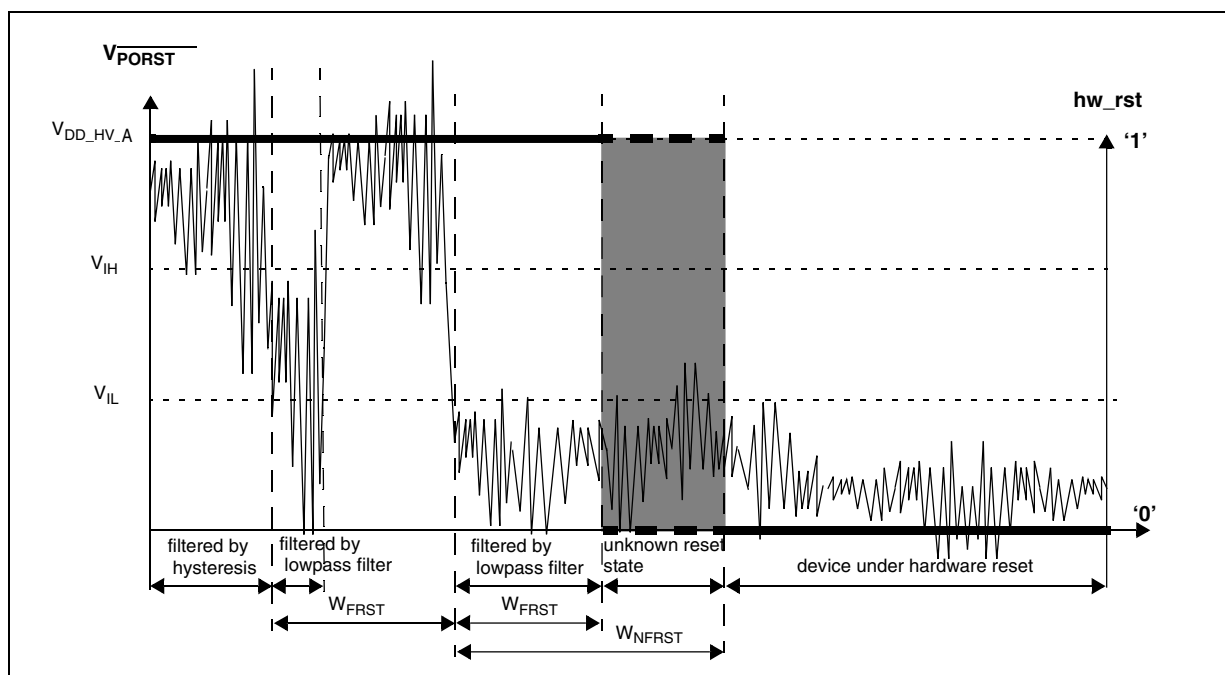


Figure 3. Noise filtering on reset signal

**Table 14. Functional reset pad electrical specifications**

| Symbol        | Parameter                                      | Conditions                                                                                            | Value |     |                       | Unit    |
|---------------|------------------------------------------------|-------------------------------------------------------------------------------------------------------|-------|-----|-----------------------|---------|
|               |                                                |                                                                                                       | Min   | Typ | Max                   |         |
| $V_{IH}$      | Input high level TTL (Schmitt Trigger)         | —                                                                                                     | 2.0   | —   | $V_{DD\_HV\_A} + 0.4$ | V       |
| $V_{IL}$      | Input low level TTL (Schmitt Trigger)          | —                                                                                                     | −0.4  | —   | 0.8                   | V       |
| $V_{HYS}$     | Input hysteresis TTL (Schmitt Trigger)         | —                                                                                                     | 300   | —   | —                     | mV      |
| $V_{DD\_POR}$ | Minimum supply for strong pull-down activation | —                                                                                                     | —     | —   | 1.2                   | V       |
| $I_{OL\_R}$   | Strong pull-down current <sup>1</sup>          | Device under power-on reset<br>$V_{DD\_HV\_A} = V_{DD\_POR}$<br>$V_{OL} = 0.35 \times V_{DD\_HV\_A}$  | 0.2   | —   | —                     | mA      |
|               |                                                | Device under power-on reset<br>$V_{DD\_HV\_A} = V_{DD\_POR}$<br>$V_{OL} = 0.35 \times V_{DD\_HV\_IO}$ | 11    | —   | —                     | mA      |
| $W_{FRST}$    | $\overline{RESET}$ input filtered pulse        | —                                                                                                     | —     | —   | 500                   | ns      |
| $W_{NFRST}$   | $\overline{RESET}$ input not filtered pulse    | —                                                                                                     | 2000  | —   | —                     | ns      |
| $I_{WPU}$     | Weak pull-up current absolute value            | $\overline{RESET}$ pin $V_{IN} = V_{DD}$                                                              | 23    | —   | 82                    | $\mu A$ |

1. Strong pull-down is active on PHASE0, PHASE1, PHASE2, and the beginning of PHASE3 for  $\overline{RESET}$ .

### 3.6 PORST electrical specifications

**Table 15. PORST electrical specifications**

| Symbol        | Parameter                      | Value |                             |     | Unit |
|---------------|--------------------------------|-------|-----------------------------|-----|------|
|               |                                | Min   | Typ                         | Max |      |
| $W_{FPORST}$  | PORST input filtered pulse     | —     | —                           | 200 | ns   |
| $W_{NFPORST}$ | PORST input not filtered pulse | 500   | —                           | —   | ns   |
| $V_{IH}$      | Input high level               | —     | $0.65 \times V_{DD\_HV\_A}$ | —   | ns   |
| $V_{IL}$      | Input low level                | —     | $0.35 \times V_{DD\_HV\_A}$ | —   | ns   |

## 4 Peripheral operating requirements and behaviours

### 4.1 Analog

#### 4.1.1 ADC electrical specifications

The device provides a 12-bit Successive Approximation Register (SAR) Analog-to-Digital Converter.

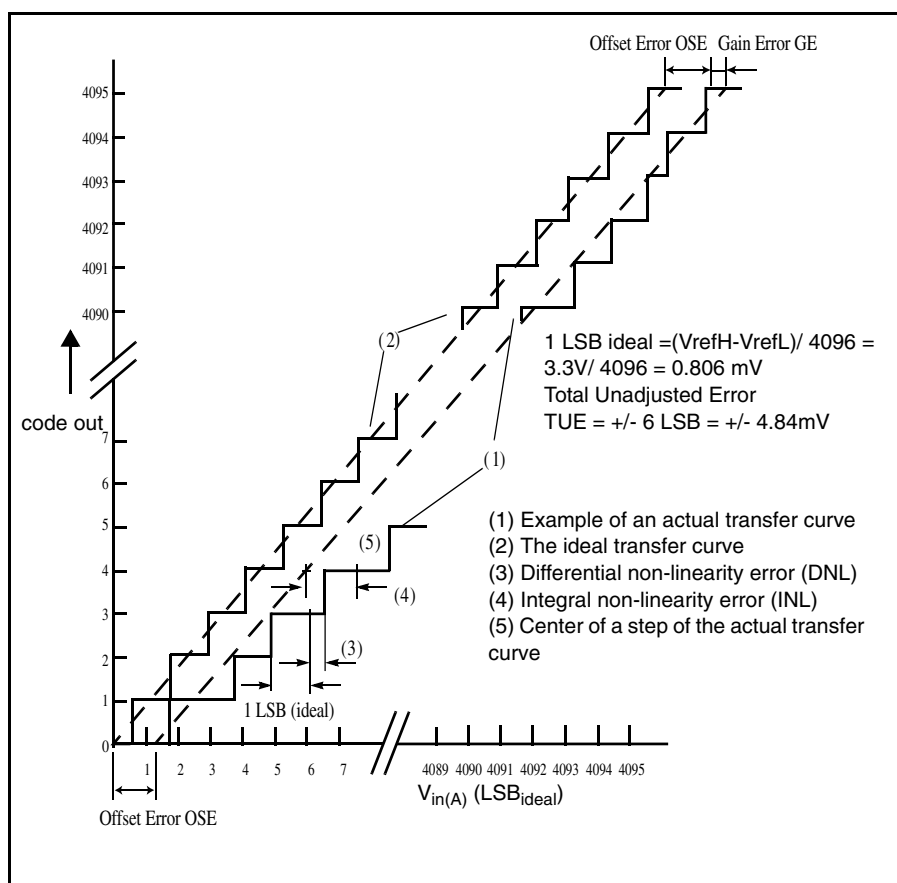


Figure 4. ADC characteristics and error definitions

### 4.1.1.1 Input impedance and ADC accuracy

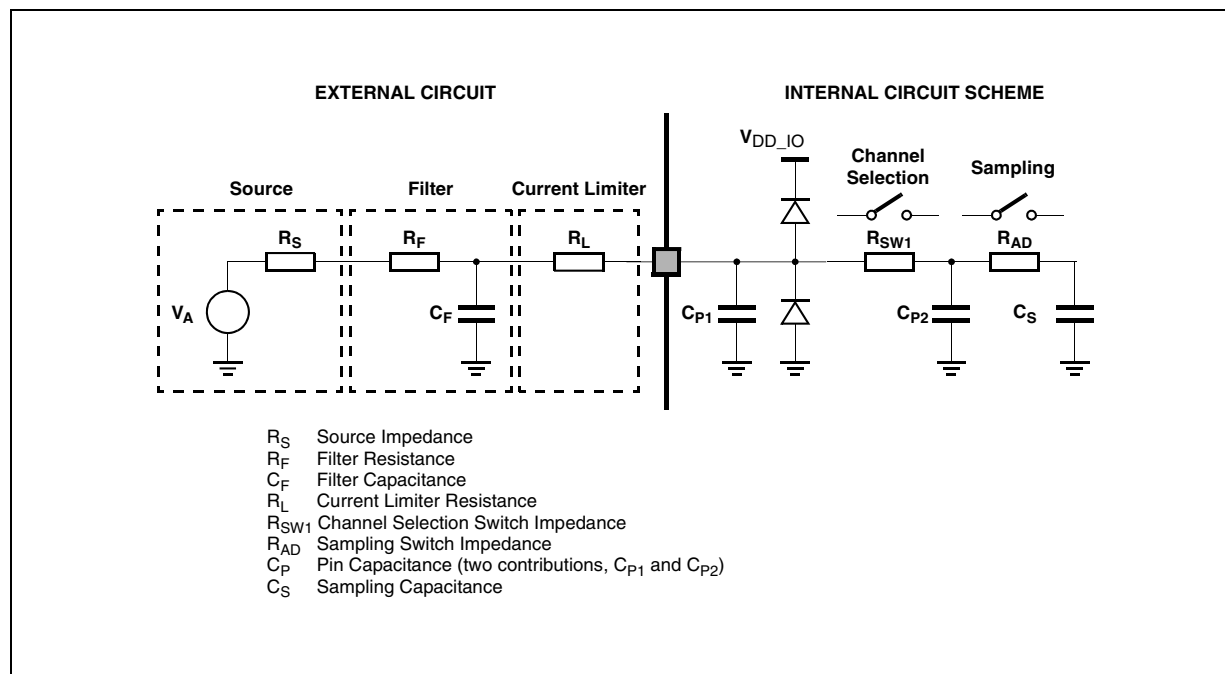


**Figure 5. Input equivalent circuit**

**Table 16. ADC conversion characteristics (for 12-bit)**

| Symbol                 | Parameter                                                                                                   | Conditions <sup>1</sup>           | Min              | Typ | Max  | Unit       |
|------------------------|-------------------------------------------------------------------------------------------------------------|-----------------------------------|------------------|-----|------|------------|
| $f_{CK}$               | ADC Clock frequency (depends on ADC configuration) (The duty cycle depends on AD_CK <sup>2</sup> frequency) | —                                 | 15.2             | 80  | 80   | MHz        |
| $f_s$                  | Sampling frequency                                                                                          | 80 MHz                            | —                | —   | 1.00 | MHz        |
| $t_{sample}$           | Sample time <sup>3</sup>                                                                                    | 80 MHz @ 100 ohm source impedance | 275              | 800 | —    | ns         |
| $t_{conv}$             | Conversion time <sup>4</sup>                                                                                | 80 MHz                            | 650              | —   | —    | ns         |
| $t_{total\_conv}$      | Total Conversion time $t_{sample} + t_{conv}$ (for standard and extended channels)                          | 80 MHz                            | 1.5 <sup>5</sup> | —   | —    | $\mu s$    |
|                        | Total Conversion time $t_{sample} + t_{conv}$ (for precision channels)                                      |                                   | 1                | —   | —    |            |
| $C_S$ <sup>6</sup>     | ADC input sampling capacitance                                                                              | —                                 | —                | 3   | 5    | pF         |
| $C_{P1}$ <sup>6</sup>  | ADC input pin capacitance 1                                                                                 | —                                 | —                | —   | 5    | pF         |
| $C_{P2}$ <sup>6</sup>  | ADC input pin capacitance 2                                                                                 | —                                 | —                | —   | 0.8  | pF         |
| $R_{SW1}$ <sup>6</sup> | Internal resistance of analog source                                                                        | $V_{REF}$ range = 4.5 to 5.5 V    | —                | —   | 0.3  | k $\Omega$ |
|                        |                                                                                                             | $V_{REF}$ range = 3.15 to 3.6 V   | —                | —   | 875  | $\Omega$   |
| $R_{AD}$ <sup>6</sup>  | Internal resistance of analog source                                                                        | —                                 | —                | —   | 825  | $\Omega$   |
| INL                    | Integral non-linearity                                                                                      | —                                 | -2               | —   | 2    | LSB        |
| DNL                    | Differential non-linearity                                                                                  | —                                 | -1               | —   | 1    | LSB        |

Table continues on the next page...

**Table 16. ADC conversion characteristics (for 12-bit) (continued)**

| Symbol                 | Parameter                           | Conditions <sup>1</sup>   | Min | Typ  | Max | Unit |
|------------------------|-------------------------------------|---------------------------|-----|------|-----|------|
| OFS                    | Offset error                        | —                         | –6  | —    | 6   | LSB  |
| GNE                    | Gain error                          | —                         | –4  | —    | 4   | LSB  |
| TUE <sub>IS1WINJ</sub> | Total unadjusted error for IS1WINJ  | Without current injection | –6  | +/-4 | 6   | LSB  |
|                        | STOP mode to Run mode recovery time |                           |     |      | < 1 | μs   |

1. Recommended operating range, unless otherwise specified and analog input voltage from  $V_{SS\_HV\_ADC1}$  to  $V_{SS\_HV\_ADC\_REF}$ .
2. The internally generated clock (known as AD\_clk or ADCK) could be same as the peripheral clock or half of the peripheral clock based on register configuration in the ADC.
3. During the sample time the input capacitance  $C_S$  can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within  $t_{sample}$ . After the end of the sample time  $t_{sample}$ , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock  $t_{sample}$  depend on programming.
4. This parameter does not include the sample time  $t_{sample}$ , but only the time for determining the digital result and the time to load the result register with the conversion result.
5. Apart from  $t_{sample}$  and  $t_{conv}$ , few cycles are used up in ADC digital interface and hence the overall throughput from the ADC is lower.
6. See [Figure 5](#).

**Table 17. ADC conversion characteristics (for 10-bit)**

| Symbol                 | Parameter                                                                                                    | Conditions <sup>1</sup>           | Min  | Typ | Max  | Unit |
|------------------------|--------------------------------------------------------------------------------------------------------------|-----------------------------------|------|-----|------|------|
| $f_{CK}$               | ADC Clock frequency (depends on ADC configuration) (The duty cycle depends on AD_CK <sup>2</sup> frequency.) | —                                 | 15.2 | 80  | 80   | MHz  |
| $f_s$                  | Sampling frequency                                                                                           | —                                 | —    | —   | 1.00 | MHz  |
| $t_{sample}$           | Sample time <sup>3</sup>                                                                                     | 80 MHz @ 100 ohm source impedance | 275  | 800 | —    | ns   |
| $t_{conv}$             | Conversion time <sup>4</sup>                                                                                 | 80 MHz                            | 550  | —   | —    | ns   |
| $t_{total\_conv}$      | Total Conversion time $t_{sample} + t_{conv}$ (for standard channels)                                        | 80 MHz                            | 1    | —   | —    | μs   |
|                        | Total Conversion time $t_{sample} + t_{conv}$ (for extended channels)                                        |                                   | 1.5  | —   | —    |      |
| $C_S$ <sup>5</sup>     | ADC input sampling capacitance                                                                               | —                                 | —    | 3   | 5    | pF   |
| $C_{P1}$ <sup>5</sup>  | ADC input pin capacitance 1                                                                                  | —                                 | —    | —   | 5    | pF   |
| $C_{P2}$ <sup>5</sup>  | ADC input pin capacitance 2                                                                                  | —                                 | —    | —   | 0.8  | pF   |
| $R_{SW1}$ <sup>5</sup> | Internal resistance of analog source                                                                         | $V_{REF}$ range = 4.5 to 5.5 V    | —    | —   | 0.3  | kΩ   |
|                        |                                                                                                              | $V_{REF}$ range = 3.15 to 3.6 V   | —    | —   | 875  | Ω    |
| $R_{AD}$ <sup>5</sup>  | Internal resistance of analog source                                                                         | —                                 | —    | —   | 825  | Ω    |
| INL                    | Integral non-linearity                                                                                       | —                                 | –2   | —   | 2    | LSB  |
| DNL                    | Differential non-linearity <sup>6</sup>                                                                      | —                                 | –1   | —   | 1    | LSB  |
| OFS                    | Offset error                                                                                                 | —                                 | –4   | —   | 4    | LSB  |
| GNE                    | Gain error                                                                                                   | —                                 | –4   | —   | 4    | LSB  |

Table continues on the next page...

**Table 17. ADC conversion characteristics (for 10-bit) (continued)**

| Symbol                                      | Parameter                              | Conditions <sup>1</sup>   | Min | Typ  | Max | Unit |
|---------------------------------------------|----------------------------------------|---------------------------|-----|------|-----|------|
| ADC Analog Pad<br>(pad going to one<br>ADC) | Max leakage                            | 150 °C                    | —   | —    | 250 | nA   |
|                                             | Max positive/negative injection        |                           | –5  | —    | 5   | mA   |
| TUE <sub>IS1WINJ</sub>                      | Total unadjusted error for IS1WINJ     | Without current injection | –4  | +/-3 | 4   | LSB  |
|                                             | STOP mode to Run mode recovery<br>time |                           |     |      | < 1 | µs   |

1.  $V_{DD} = 3.3\text{ V} - 5.5$ ,  $T_J = -40$  to  $+150\text{ °C}$ , unless otherwise specified and analog input voltage from  $V_{SS\_HV\_ADC0}$  to  $V_{DD\_HV\_ADC0}$ .
2. The internally generated clock (known as AD\_clk or ADCK) could be same as the peripheral clock or half of the peripheral clock based on register configuration in the ADC.
3. During the sample time the input capacitance  $C_S$  can be charged/discharged by the external source. The internal resistance of the analog source must allow the capacitance to reach its final voltage level within  $t_{\text{sample}}$ . After the end of the sample time  $t_{\text{sample}}$ , changes of the analog input voltage have no effect on the conversion result. Values for the sample clock  $t_{\text{sample}}$  depend on programming.
4. This parameter does not include the sample time  $t_{\text{sample}}$ , but only the time for determining the digital result and the time to load the result register with the conversion result.
5. See [Figure 5](#)
6. No missing codes.

**Table 18. ADC supply configurations**

|                      | VALID CASE 1                                                       | VALID CASE 2                                                      | VALID CASE 3                                                      | VALID CASE 4                                                      |
|----------------------|--------------------------------------------------------------------|-------------------------------------------------------------------|-------------------------------------------------------------------|-------------------------------------------------------------------|
| VDD_HV_ADC1          | 5V                                                                 | 5V                                                                | 3.3V                                                              | 3.3V                                                              |
| VDD_HV_ADC1_REF      | 3.3V                                                               | 5V                                                                | 3.3V                                                              | 5V                                                                |
| ADC1 input pin range | 0V to IO segment<br>supply voltage where<br>that input pin resides | 0 to IO segment supply<br>voltage where that input<br>pin resides | 0 to IO segment supply<br>voltage where that input<br>pin resides | 0 to IO segment supply<br>voltage where that input<br>pin resides |
| ADC1 result          | Valid up to 3.3V, then<br>full-scale reached                       | Valid up to 5V                                                    | Valid up to 3.3V, then<br>full-scale reached                      | Valid up to 5V                                                    |

**NOTE**

The ADC input pins sit across all three I/O segments,  
VDD\_HV\_A, VDD\_HV\_B and VDD\_HV\_C.

**4.1.2 Analogue Comparator (CMP) electrical specifications****Table 19. Comparator and 6-bit DAC electrical specifications**

| Symbol            | Description                                     | Min.            | Typ. | Max.                          | Unit |
|-------------------|-------------------------------------------------|-----------------|------|-------------------------------|------|
| I <sub>DDHS</sub> | Supply current, High-speed mode (EN=1, PMODE=1) | —               | —    | 250                           | µA   |
| I <sub>DDL</sub>  | Supply current, low-speed mode (EN=1, PMODE=0)  | —               | 5    | 10                            | µA   |
| V <sub>AIN</sub>  | Analog input voltage                            | V <sub>SS</sub> | —    | V <sub>IN1_CMP_RE<br/>F</sub> | V    |
| V <sub>AIO</sub>  | Analog input offset voltage                     | -20             | —    | 20                            | mV   |

Table continues on the next page...

**Table 19. Comparator and 6-bit DAC electrical specifications (continued)**

| Symbol      | Description                                                          | Min.                  | Typ. | Max. | Unit             |
|-------------|----------------------------------------------------------------------|-----------------------|------|------|------------------|
| $V_H$       | Analog comparator hysteresis <sup>1</sup>                            |                       |      |      |                  |
|             | • CR0[HYSTCTR] = 0                                                   | —                     | 0    | —    | mV               |
|             | • CR0[HYSTCTR] = 10                                                  | —                     | 10   | —    | mV               |
|             | • CR0[HYSTCTR] = 20                                                  | —                     | 20   | —    | mV               |
|             | • CR0[HYSTCTR] = 30                                                  | —                     | 30   | —    | mV               |
| $V_{CMPOH}$ | Output high                                                          | $V_{DD\_HV\_A} - 0.5$ | —    | —    | V                |
| $V_{CMPOI}$ | Output low                                                           | —                     | —    | 0.5  | V                |
| $t_{DHS}$   | Propagation Delay, High Speed Mode (+/-100mV)                        | —                     | 50   | —    | ns               |
|             | Propagation Delay, High Speed Mode (+/-20mV)                         | —                     | 120  | —    | ns               |
|             | Analog comparator initialization delay, High Speed Mode <sup>2</sup> | —                     | 4    |      | $\mu$ s          |
|             | Analog comparator initialization delay, Low Power Mode               | —                     | 100  |      | $\mu$ s          |
| $I_{DAC6b}$ | 6-bit DAC current adder (when enabled)                               |                       |      |      |                  |
|             | 3.3V Reference Voltage                                               | —                     | 6    | 9    | $\mu$ A          |
|             | 5V Reference Voltage                                                 | —                     | 10   | 16   | $\mu$ A          |
| INL         | 6-bit DAC integral non-linearity                                     | -0.5                  | —    | 0.5  | LSB <sup>3</sup> |
| DNL         | 6-bit DAC differential non-linearity                                 | -0.3                  | —    | 0.3  | LSB              |

1. Typical hysteresis is measured with input voltage range limited to 0.6 to  $V_{DD\_HV\_A} - 0.6V$ .
2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to DACEN, VRSEL, PSEL, MSEL, VOSEL) and the comparator output settling to a stable level.
3. 1 LSB =  $V_{reference}/64$

## 4.2 Clocks and PLL interfaces modules

### 4.2.1 Main oscillator electrical characteristics

This device provides a driver for oscillator in pierce configuration with amplitude control. Controlling the amplitude allows a more sinusoidal oscillation, reducing in this way the EMI. Other benefits arises by reducing the power consumption. This Loop Controlled Pierce (LCP mode) requires good practices to reduce the stray capacitance of traces between crystal and MCU.

An operation in Full Swing Pierce (FSP mode), implemented by an inverter is also available in case of parasitic capacitances and cannot be reduced by using crystal with high equivalent series resistance. For this mode, a special care needs to be taken regarding the serial resistance used to avoid the crystal overdrive.

Other two modes called External (EXT Wave) and disable (OFF mode) are provided. For EXT Wave, the drive is disabled and an external source of clock within CMOS level based in analog oscillator supply can be used. When OFF, EXTAL is pulled down by 240 Kohms resistor and the feedback resistor remains active connecting XTAL through EXTAL by 1M resistor.

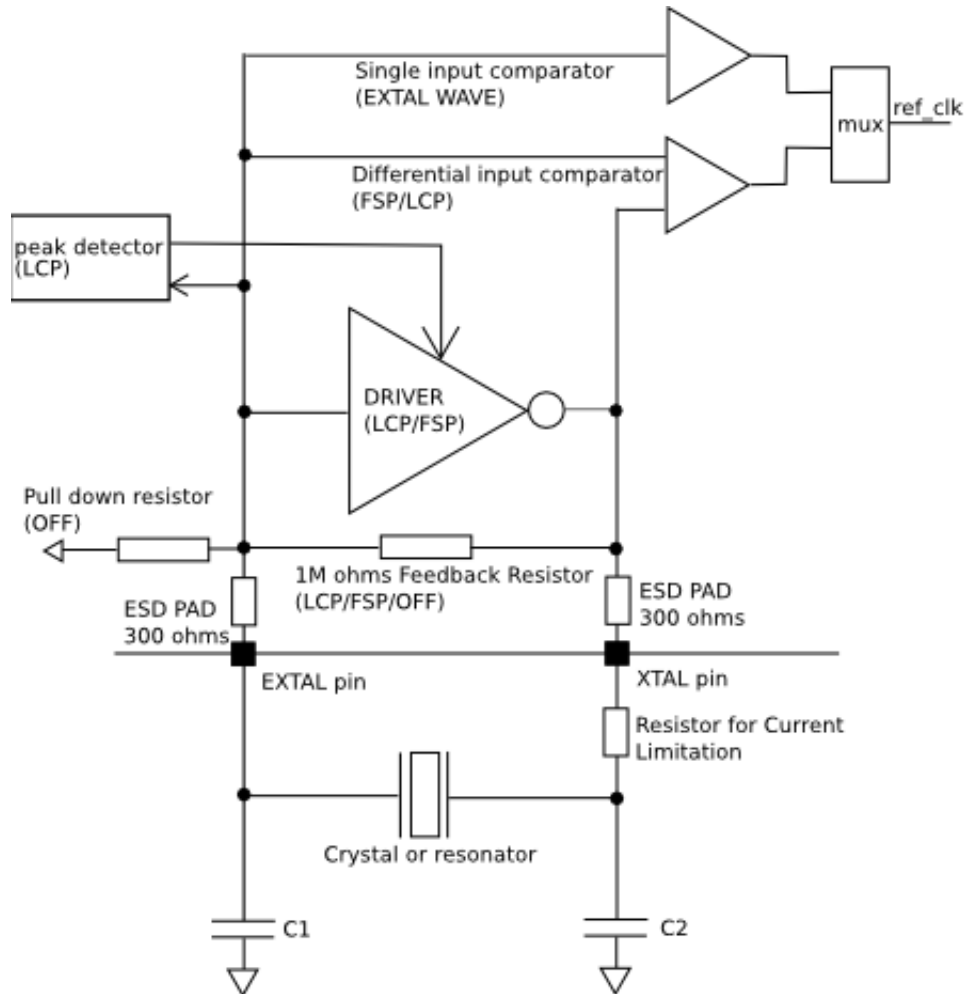


**Figure 6. Oscillator connections scheme**

**Table 20. Main oscillator electrical characteristics**

| Symbol        | Parameter               | Mode    | Conditions | Min | Typ | Max | Unit |
|---------------|-------------------------|---------|------------|-----|-----|-----|------|
| $f_{XOSCHS}$  | Oscillator frequency    | FSP/LCP |            | 4   |     | 40  | MHz  |
| $g_{mXOSCHS}$ | Driver Transconductance | FSP/LCP | 1          |     | 23  |     | mA/V |

*Table continues on the next page...*

**Table 20. Main oscillator electrical characteristics (continued)**

| Symbol                | Parameter                             | Mode                 | Conditions            | Min  | Typ  | Max  | Unit            |
|-----------------------|---------------------------------------|----------------------|-----------------------|------|------|------|-----------------|
| V <sub>XOSCHS</sub>   | Oscillation Amplitude                 | LCP <sup>1,2</sup>   | 4 MHz                 |      | 1.0  |      | V <sub>PP</sub> |
|                       |                                       |                      | 8 MHz                 |      | 1.0  |      |                 |
|                       |                                       |                      | 16 MHz                |      | 1.0  |      |                 |
|                       |                                       |                      | 40 MHz                |      | 0.8  |      |                 |
| T <sub>XOSCHSSU</sub> | Startup time                          | FSP/LCP <sup>3</sup> | 4-40 MHz              |      | 1    |      | ms              |
|                       | Supply current                        | FSP                  | 8 MHz                 |      | 2.2  |      | mA              |
|                       |                                       |                      | 16 MHz                |      | 2.2  |      |                 |
|                       |                                       |                      | 40 MHz                |      | 3.2  |      |                 |
|                       |                                       | LCP                  | 8 MHz                 |      | 141  |      | uA              |
|                       |                                       |                      | 16 MHz                |      | 252  |      |                 |
|                       |                                       |                      | 40 MHz                |      | 518  |      |                 |
| V <sub>IH</sub>       | Input High level CMOS Schmitt trigger | EXT Wave             | Oscillator supply=3.3 | 1.25 | 1.45 |      | V               |
| V <sub>IL</sub>       | Input low level CMOS Schmitt trigger  | EXT Wave             | Oscillator supply=3.3 |      |      | 1.95 | V               |

1. Values are very dependent on crystal or resonator used and parasitic capacitance observed in the board.
2. Typ value for oscillator supply 3.3 V@27 °C
3. Values are very dependent on crystal or resonator used and parasitic capacitance observed in the board

## 4.2.2 32 kHz Oscillator electrical specifications

**Table 21. 32 kHz oscillator electrical specifications**

| Symbol              | Parameter                                 | Condition | Min | Typ | Max | Unit |
|---------------------|-------------------------------------------|-----------|-----|-----|-----|------|
| f <sub>osc_lo</sub> | Oscillator crystal or resonator frequency |           | 32  |     | 40  | KHz  |
| t <sub>cst</sub>    | Crystal Start-up Time <sup>1,2</sup>      |           |     |     | 2   | s    |

1. This parameter is characterized before qualification rather than 100% tested.
2. Proper PC board layout procedures must be followed to achieve specifications.

## 4.2.3 16 MHz RC Oscillator electrical specifications

**Table 22. 16 MHz RC Oscillator electrical specifications**

| Symbol              | Parameter            | Conditions | Value |     |     | Unit |
|---------------------|----------------------|------------|-------|-----|-----|------|
|                     |                      |            | Min   | Typ | Max |      |
| F <sub>Target</sub> | IRC target frequency | —          | —     | 16  | —   | MHz  |

Table continues on the next page...

**Table 22. 16 MHz RC Oscillator electrical specifications (continued)**

| Symbol          | Parameter                                 | Conditions          | Value |     |       | Unit    |
|-----------------|-------------------------------------------|---------------------|-------|-----|-------|---------|
|                 |                                           |                     | Min   | Typ | Max   |         |
| $F_{Untrimmed}$ | IRC frequency (untrimmed)                 | —                   | 10.16 | —   | 22.02 | MHz     |
| PTA             | IRC frequency variation after trimming    | —                   | -5    | —   | 5     | %       |
| $T_{startup}$   | Startup time                              | —                   |       | —   | 1     | us      |
| $T_{STJIT}$     | Cycle to cycle jitter                     |                     | —     | —   | 1.5   | %       |
| $T_{LTJIT}$     | Long term jitter                          |                     | —     | —   | 0.02  | %       |
| $I_{VDDHV}$     | Current consumption on 3.3 V power supply | After $T_{startup}$ | —     | —   | 75    | $\mu A$ |
| $I_{VDDL V}$    | Current consumption on 1.2 V power supply | After $T_{startup}$ | —     | —   | 25    | $\mu A$ |

**NOTE**

The above start up time of 1 us is equivalent to 16 cycles of 16 MHz.

**4.2.4 128 KHz Internal RC oscillator Electrical specifications****Table 23. 128 KHz Internal RC oscillator electrical specifications**

| Symbol       | Parameter              | Condition     | Min | Typ | Max  | Unit    |
|--------------|------------------------|---------------|-----|-----|------|---------|
| $F_{oscu}^1$ | Oscillator frequency   | Uncalibrated  | 96  | 128 | 200  | KHz     |
| $F_{osc}^1$  |                        | Calibrated    | 122 | 128 | 134  | KHz     |
|              | Temperature dependence |               |     |     | 270  | ppm/C   |
|              | Supply dependence      |               |     |     | 10   | %/V     |
|              | Supply current         | Clock running |     |     | 2.75 | $\mu A$ |
|              |                        | Clock stopped |     |     | 200  | nA      |

1.  $V_{dd}=1.2\text{ V}$ ,  $1.32\text{ V}$ ,  $T_a=-40\text{ C}$ ,  $125\text{ C}$

**4.2.5 PLL electrical specifications****Table 24. PLL electrical specifications**

| Parameter              | Min  | Typ | Max  | Unit | Comments          |
|------------------------|------|-----|------|------|-------------------|
| Input Frequency        | 8    |     | 40   | MHz  |                   |
| Input Clock Low Level  | 0    | 0   | 0    |      | Square wave clock |
| Input Clock High Level | 1.08 | 1.2 | 1.32 | V    | Square wave clock |
| VCO Frequency Range    | 600  |     | 1280 | MHz  |                   |

Table continues on the next page...

**Table 24. PLL electrical specifications  
(continued)**

| Parameter                            | Min       | Typ             | Max                          | Unit | Comments                                                       |
|--------------------------------------|-----------|-----------------|------------------------------|------|----------------------------------------------------------------|
| Duty Cycle at pllclkout              | 48%       | (N+1)/<br>(2xN) | 52%                          |      | with even division at output with<br>odd division(N) at output |
| Regulator Maximum Output Current     | 0.75      |                 |                              | mA   |                                                                |
| Analog Supply                        | 1.08      | 1.2             | 1.32                         |      |                                                                |
| Digital Supply (V <sub>DD_LV</sub> ) | 1.08      | 1.2             | 1.32                         |      |                                                                |
| Period Jitter                        |           |                 | See Table 25                 | ps   | NON SSCG mode                                                  |
| TIE                                  |           |                 | See Table 25                 |      | at 960 M Integrated over 1MHz<br>offset not valid in SSCG mode |
| Modulation Depth (Center Spread)     | +/- 0.25% |                 | +/- 4.0%                     |      |                                                                |
| Modulation Depth (Down Spread)       | +/- 0.5%  |                 | +/- 8.0%                     |      |                                                                |
| Modulation Frequency                 |           |                 | 32                           | KHz  |                                                                |
| Lock Time                            | 20        |                 | 60                           | μs   | Calibration mode                                               |
|                                      | 10        |                 | 30                           | μs   | Calibration bypass mode (wake-<br>up mode)                     |
| PLL reset assertion time             |           |                 | 5                            | μs   |                                                                |
| Power Consumption                    |           |                 | 1 mA (avdd)<br>0.5 mA (dvdd) |      | at 1280 MHz VCO clock<br>T <sub>A</sub> =25°C                  |

**Table 25. Jitter calculation**

| Type of jitter                        | Jitter due to<br>Supply<br>Noise (ps)<br>J <sub>SN</sub> <sup>1</sup> | Jitter due to<br>Fractional Mode<br>(ps) J <sub>SDM</sub> <sup>2</sup> | Jitter due to<br>Fractional Mode<br>J <sub>SSCG</sub> (ps) <sup>3</sup> | 1 Sigma<br>Random<br>Jitter J <sub>RJ</sub><br>(ps) <sup>4</sup> | Total Period Jitter (ps)                                                                        |
|---------------------------------------|-----------------------------------------------------------------------|------------------------------------------------------------------------|-------------------------------------------------------------------------|------------------------------------------------------------------|-------------------------------------------------------------------------------------------------|
| Period Jitter                         | 60 ps                                                                 | 3% of pllclkout1,2                                                     | Modulation depth                                                        | 0.1% of<br>pllclkout1,2                                          | +/- (J <sub>SN</sub> +J <sub>SDM</sub> +J <sub>SSCG</sub> +N <sup>[4]</sup><br>xJ <sub>RJ</sub> |
| Long Term Jitter<br>(Integer Mode)    |                                                                       |                                                                        |                                                                         |                                                                  | N x J <sub>RJ</sub>                                                                             |
| Long Term jitter<br>(Fractional Mode) |                                                                       |                                                                        |                                                                         |                                                                  | N x J <sub>RJ</sub>                                                                             |

1. This jitter component is due to self noise generated due to bond wire inductances on different PLL supplies. The jitter value is valid for inductor value of 5nH or less each on avdd, avss, dvdd, dvss.
2. This jitter component is added when the PLL is working in the fractional mode.
3. This jitter component is added when the PLL is working in the Spread Spectrum Mode. Else it is 0.
4. The value of N is dependent on the accuracy requirement of the application. See Table 26.

**Table 26. Percentage of sample exceeding specified value of jitter**

| N | Percentage of samples exceeding specified value of jitter<br>(%) |
|---|------------------------------------------------------------------|
| 1 | 31.73                                                            |
| 2 | 4.55                                                             |
| 3 | 0.27                                                             |

Table continues on the next page...

**Table 26. Percentage of sample exceeding specified value of jitter (continued)**

| N | Percentage of samples exceeding specified value of jitter (%) |
|---|---------------------------------------------------------------|
| 4 | $6.30 \times 1e-03$                                           |
| 5 | $5.63 \times 1e-05$                                           |
| 6 | $2.00 \times 1e-07$                                           |
| 7 | $2.82 \times 1e-10$                                           |

## 4.3 Memory interfaces

### 4.3.1 Flash memory program and erase specifications

#### NOTE

All timing, voltage, and current numbers specified in this section are defined for a single embedded flash memory within an SoC, and represent average currents for given supplies and operations.

Table 27 shows the estimated Program/Erase times.

**Table 27. Flash memory program and erase specifications**

| Symbol               | Characteristic <sup>1</sup>        | Typ <sup>2</sup> | Factory Programming <sup>3, 4</sup> |                        | Field Update                     |                            |                              | Unit |
|----------------------|------------------------------------|------------------|-------------------------------------|------------------------|----------------------------------|----------------------------|------------------------------|------|
|                      |                                    |                  | Initial Max                         | Initial Max, Full Temp | Typical End of Life <sup>5</sup> | Lifetime Max <sup>6</sup>  |                              |      |
|                      |                                    |                  |                                     |                        |                                  | 20°C ≤T <sub>A</sub> ≤30°C | -40°C ≤T <sub>J</sub> ≤150°C |      |
| t <sub>dwpgm</sub>   | Doubleword (64 bits) program time  | 43               | 100                                 | 150                    | 55                               | 500                        |                              | μs   |
| t <sub>ppgm</sub>    | Page (256 bits) program time       | 73               | 200                                 | 300                    | 108                              | 500                        |                              | μs   |
| t <sub>qppgn</sub>   | Quad-page (1024 bits) program time | 268              | 800                                 | 1,200                  | 396                              | 2,000                      |                              | μs   |
| t <sub>16kers</sub>  | 16 KB Block erase time             | 168              | 290                                 | 320                    | 250                              | 1,000                      |                              | ms   |
| t <sub>16kpgn</sub>  | 16 KB Block program time           | 34               | 45                                  | 50                     | 40                               | 1,000                      |                              | ms   |
| t <sub>32kers</sub>  | 32 KB Block erase time             | 217              | 360                                 | 390                    | 310                              | 1,200                      |                              | ms   |
| t <sub>32kpgm</sub>  | 32 KB Block program time           | 69               | 100                                 | 110                    | 90                               | 1,200                      |                              | ms   |
| t <sub>64kers</sub>  | 64 KB Block erase time             | 315              | 490                                 | 590                    | 420                              | 1,600                      |                              | ms   |
| t <sub>64kpgm</sub>  | 64 KB Block program time           | 138              | 180                                 | 210                    | 170                              | 1,600                      |                              | ms   |
| t <sub>256kers</sub> | 256 KB Block erase time            | 884              | 1,520                               | 2,030                  | 1,080                            | 4,000                      | —                            | ms   |
| t <sub>256kpgm</sub> | 256 KB Block program time          | 552              | 720                                 | 880                    | 650                              | 4,000                      | —                            | ms   |

## Memory interfaces

1. Program times are actual hardware programming times and do not include software overhead. Block program times assume quad-page programming.
2. Typical program and erase times represent the median performance and assume nominal supply values and operation at 25 °C. Typical program and erase times may be used for throughput calculations.
3. Conditions:  $\leq 150$  cycles, nominal voltage.
4. Plant Programming times provide guidance for timeout limits used in the factory.
5. Typical End of Life program and erase times represent the median performance and assume nominal supply values. Typical End of Life program and erase values may be used for throughput calculations.
6. Conditions:  $-40^{\circ}\text{C} \leq T_J \leq 150^{\circ}\text{C}$ , full spec voltage.

### 4.3.2 Flash memory Array Integrity and Margin Read specifications

**Table 28. Flash memory Array Integrity and Margin Read specifications**

| Symbol          | Characteristic                                               | Min    | Typical | Max <sup>1, 1</sup>                 | Units <sup>2, 2</sup> |
|-----------------|--------------------------------------------------------------|--------|---------|-------------------------------------|-----------------------|
| $t_{ai16kseq}$  | Array Integrity time for sequential sequence on 16KB block.  | —      | —       | 512 x $T_{period} \times N_{read}$  | —                     |
| $t_{ai32kseq}$  | Array Integrity time for sequential sequence on 32KB block.  | —      | —       | 1024 x $T_{period} \times N_{read}$ | —                     |
| $t_{ai64kseq}$  | Array Integrity time for sequential sequence on 64KB block.  | —      | —       | 2048 x $T_{period} \times N_{read}$ | —                     |
| $t_{ai256kseq}$ | Array Integrity time for sequential sequence on 256KB block. | —      | —       | 8192 x $T_{period} \times N_{read}$ | —                     |
| $t_{mr16kseq}$  | Margin Read time for sequential sequence on 16KB block.      | 73.81  | —       | 110.7                               | $\mu\text{s}$         |
| $t_{mr32kseq}$  | Margin Read time for sequential sequence on 32KB block.      | 128.43 | —       | 192.6                               | $\mu\text{s}$         |
| $t_{mr64kseq}$  | Margin Read time for sequential sequence on 64KB block.      | 237.65 | —       | 356.5                               | $\mu\text{s}$         |
| $t_{mr256kseq}$ | Margin Read time for sequential sequence on 256KB block.     | 893.01 | —       | 1,339.5                             | $\mu\text{s}$         |

1. Array Integrity times need to be calculated and is dependant on system frequency and number of clocks per read. The equation presented require  $T_{period}$  (which is the unit accurate period, thus for 200 MHz,  $T_{period}$  would equal  $5e-9$ ) and  $N_{read}$  (which is the number of clocks required for read, including pipeline contribution. Thus for a read setup that requires 6 clocks to read with no pipeline,  $N_{read}$  would equal 6. For a read setup that requires 6 clocks to read, and has the address pipeline set to 2,  $N_{read}$  would equal 4 (or  $6 - 2$ ).)
2. The units for Array Integrity are determined by the period of the system clock. If unit accurate period is used in the equation, the results of the equation are also unit accurate.

### 4.3.3 Flash memory module life specifications

**Table 29. Flash memory module life specifications**

| Symbol           | Characteristic                                                                              | Conditions | Min     | Typical | Units      |
|------------------|---------------------------------------------------------------------------------------------|------------|---------|---------|------------|
| Array P/E cycles | Number of program/erase cycles per block for 16 KB, 32 KB and 64 KB blocks. <sup>1, 1</sup> | —          | 250,000 | —       | P/E cycles |
|                  | Number of program/erase cycles per block for 256 KB blocks. <sup>2, 2</sup>                 | —          | 1,000   | 250,000 | P/E cycles |

Table continues on the next page...

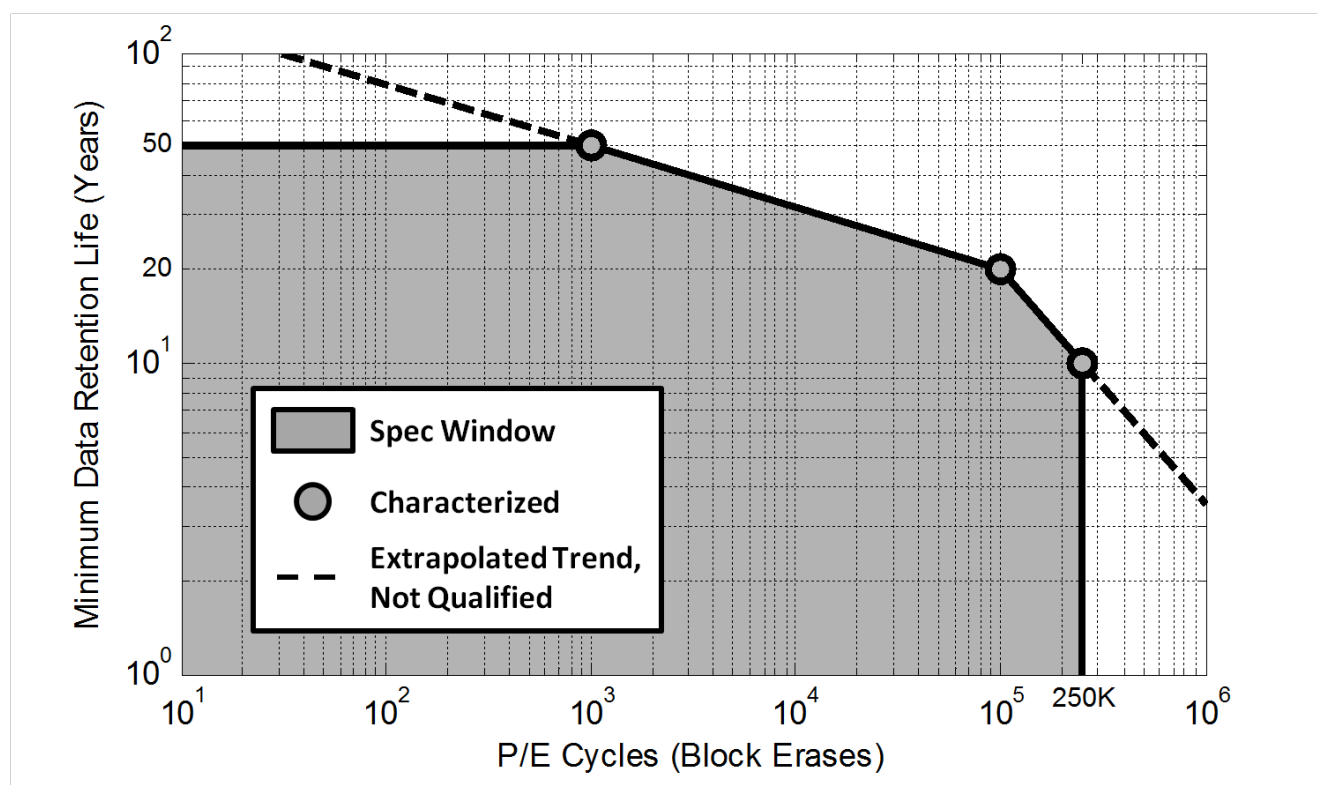
**Table 29. Flash memory module life specifications (continued)**

| Symbol         | Characteristic          | Conditions                        | Min | Typical | Units |
|----------------|-------------------------|-----------------------------------|-----|---------|-------|
| Data retention | Minimum data retention. | Blocks with 0 - 1,000 P/E cycles. | 50  | —       | Years |
|                |                         | Blocks with 100,000 P/E cycles.   | 20  | —       | Years |
|                |                         | Blocks with 250,000 P/E cycles.   | 10  | —       | Years |

1. Program and erase supported across standard temperature specs.
2. Program and erase supported across standard temperature specs.

#### 4.3.4 Data retention vs program/erase cycles

Graphically, Data Retention versus Program/Erase Cycles can be represented by the following figure. The spec window represents qualified limits. The extrapolated dotted line demonstrates technology capability, however is beyond the qualification limits.



### 4.3.5 Flash memory AC timing specifications

Table 30. Flash memory AC timing specifications

| Symbol        | Characteristic                                                                                                                                                                                                               | Min                                              | Typical                                       | Max                                              | Units   |
|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------|-----------------------------------------------|--------------------------------------------------|---------|
| $t_{psus}$    | Time from setting the MCR-PSUS bit until MCR-DONE bit is set to a 1.                                                                                                                                                         | —                                                | 7<br>plus four<br>system<br>clock<br>periods  | 9.1<br>plus four<br>system<br>clock<br>periods   | $\mu s$ |
| $t_{esus}$    | Time from setting the MCR-ESUS bit until MCR-DONE bit is set to a 1.                                                                                                                                                         | —                                                | 16<br>plus four<br>system<br>clock<br>periods | 20.8<br>plus four<br>system<br>clock<br>periods  | $\mu s$ |
| $t_{res}$     | Time from clearing the MCR-ESUS or PSUS bit with EHV = 1 until DONE goes low.                                                                                                                                                | —                                                | —                                             | 100                                              | ns      |
| $t_{done}$    | Time from 0 to 1 transition on the MCR-EHV bit initiating a program/erase until the MCR-DONE bit is cleared.                                                                                                                 | —                                                | —                                             | 5                                                | ns      |
| $t_{dones}$   | Time from 1 to 0 transition on the MCR-EHV bit aborting a program/erase until the MCR-DONE bit is set to a 1.                                                                                                                | —                                                | 16<br>plus four<br>system<br>clock<br>periods | 20.8<br>plus four<br>system<br>clock<br>periods  | $\mu s$ |
| $t_{drcv}$    | Time to recover once exiting low power mode.                                                                                                                                                                                 | 16<br>plus seven<br>system<br>clock<br>periods.  | —                                             | 45<br>plus seven<br>system<br>clock<br>periods   | $\mu s$ |
| $t_{aistart}$ | Time from 0 to 1 transition of UT0-AIE initiating a Margin Read or Array Integrity until the UT0-AID bit is cleared. This time also applies to the resuming from a suspend or breakpoint by clearing AISUS or clearing NAIBP | —                                                | —                                             | 5                                                | ns      |
| $t_{aistop}$  | Time from 1 to 0 transition of UT0-AIE initiating an Array Integrity abort until the UT0-AID bit is set. This time also applies to the UT0-AISUS to UT0-AID setting in the event of a Array Integrity suspend request.       | —                                                | —                                             | 80<br>plus fifteen<br>system<br>clock<br>periods | ns      |
| $t_{mrstop}$  | Time from 1 to 0 transition of UT0-AIE initiating a Margin Read abort until the UT0-AID bit is set. This time also applies to the UT0-AISUS to UT0-AID setting in the event of a Margin Read suspend request.                | 10.36<br>plus four<br>system<br>clock<br>periods | —                                             | 20.42<br>plus four<br>system<br>clock<br>periods | $\mu s$ |

### 4.3.6 Flash read wait state and address pipeline control settings

The following table describes the recommended RWSC and APC settings at various operating frequencies based on specified intrinsic flash access times of the flash module controller array at 125 °C.

**Table 31. Flash Read Wait State and Address Pipeline Control Guidelines**

| Operating frequency ( $f_{\text{sys}}$ ) <sup>1</sup> | RWSC | APC | Flash read latency on mini-cache miss (# of $f_{\text{sys}}$ clock periods) | Flash read latency on mini-cache hit (# of $f_{\text{sys}}$ clock periods) |
|-------------------------------------------------------|------|-----|-----------------------------------------------------------------------------|----------------------------------------------------------------------------|
| 40 MHz                                                | 1    | 0,1 | 3                                                                           | 1                                                                          |
| 80 MHz                                                | 2    | 0,1 | 5                                                                           | 1                                                                          |
| 120 MHz                                               | 3    | 0,1 | 6                                                                           | 1                                                                          |
| 160 MHz                                               | 4    | 0,1 | 7                                                                           | 1                                                                          |

1. Packaged parts (-40 to 150°C)

## 4.4 Communication interfaces

### 4.4.1 DSPI timing

**Table 32. DSPI electrical specifications**

| No | Symbol            | Parameter               | Conditions                            | High Speed Mode         |                         | low Speed mode |     | Unit |
|----|-------------------|-------------------------|---------------------------------------|-------------------------|-------------------------|----------------|-----|------|
|    |                   |                         |                                       | Min                     | Max                     | Min            | Max |      |
| 1  | $t_{\text{SCK}}$  | DSPI cycle time         | Master (MTFE = 0)                     | 25                      | —                       | 50             | —   | ns   |
|    |                   |                         | Slave (MTFE = 0)                      | 40                      | —                       | 60             | —   |      |
| 2  | $t_{\text{CSC}}$  | PCS to SCK delay        | —                                     | 16                      | —                       | —              | —   | ns   |
| 3  | $t_{\text{ASC}}$  | After SCK delay         | —                                     | 16                      | —                       | —              | —   | ns   |
| 4  | $t_{\text{SDC}}$  | SCK duty cycle          | —                                     | $t_{\text{SCK}}/2 - 10$ | $t_{\text{SCK}}/2 + 10$ | —              | —   | ns   |
| 5  | $t_{\text{A}}$    | Slave access time       | SS active to SOUT valid               | —                       | 40                      | —              | —   | ns   |
| 6  | $t_{\text{DIS}}$  | Slave SOUT disable time | SS inactive to SOUT High-Z or invalid | —                       | 10                      | —              | —   | ns   |
| 7  | $t_{\text{PCSC}}$ | PCSx to PCSS time       | —                                     | 13                      | —                       | —              | —   | ns   |
| 8  | $t_{\text{PASC}}$ | PCSS to PCSx time       | —                                     | 13                      | —                       | —              | —   | ns   |

Table continues on the next page...

**Table 32. DSPI electrical specifications (continued)**

| No | Symbol    | Parameter                   | Conditions                  | High Speed Mode |     | low Speed mode    |                 | Unit |
|----|-----------|-----------------------------|-----------------------------|-----------------|-----|-------------------|-----------------|------|
|    |           |                             |                             | Min             | Max | Min               | Max             |      |
| 9  | $t_{SUI}$ | Data setup time for inputs  | Master (MTFE = 0)           | NA              | —   | 20                | —               | ns   |
|    |           |                             | Slave                       | 2               | —   | 2                 | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 0) | 15              | —   | 8 <sup>1, 1</sup> | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 1) | 15              | —   | 20                | —               |      |
| 10 | $t_{HI}$  | Data hold time for inputs   | Master (MTFE = 0)           | NA              | —   | -5                | —               | ns   |
|    |           |                             | Slave                       | 4               | —   | 4                 | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 0) | 0               | —   | 11 <sup>1</sup>   | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 1) | 0               | —   | -5                | —               |      |
| 11 | $t_{SUO}$ | Data valid (after SCK edge) | Master (MTFE = 0)           | —               | NA  | —                 | 4               | ns   |
|    |           |                             | Slave                       | —               | 15  | —                 | 23              |      |
|    |           |                             | Master (MTFE = 1, CPHA = 0) | —               | 4   | —                 | 16 <sup>1</sup> |      |
|    |           |                             | Master (MTFE = 1, CPHA = 1) | —               | 4   | —                 | 4               |      |
| 12 | $t_{HO}$  | Data hold time for outputs  | Master (MTFE = 0)           | NA              | —   | -2                | —               | ns   |
|    |           |                             | Slave                       | 4               | —   | 6                 | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 0) | -2              | —   | 10 <sup>1</sup>   | —               |      |
|    |           |                             | Master (MTFE = 1, CPHA = 1) | -2              | —   | -2                | —               |      |

1. SMPL\_PTR should be set to 1

## NOTE

### Restriction For High Speed modes

- DSPI2, DSPI3, SPI1 and SPI2 will support 40MHz Master mode SCK
- DSPI2, DSPI3, SPI1 and SPI2 will support 25MHz Slave SCK frequency
- Only one {SIN, SOUT and SCK} group per DSPI/SPI will support high frequency mode
- For Master mode MTFE will be 1 for high speed mode
- For high speed slaves, their master have to be in MTFE=1 mode or should be able to support 15ns tSUO delay

**NOTE**

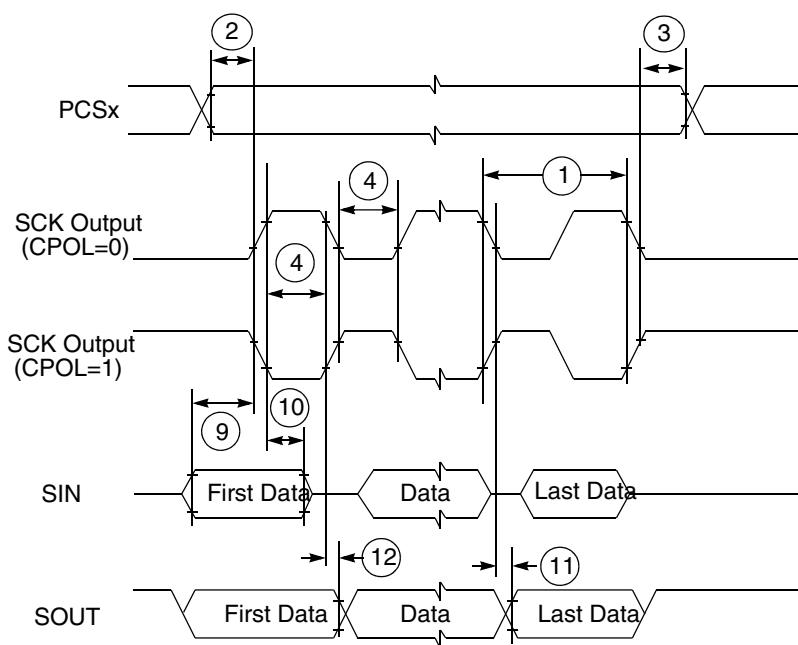
For numbers shown in the following figures, see [Table 32](#)

**Table 33. Continuous SCK timing**

| Spec | Characteristics     | Pad Drive/Load | Value   |         |
|------|---------------------|----------------|---------|---------|
|      |                     |                | Minimum | Maximum |
| tSCK | SCK cycle timing    | strong/50pf    | 100ns   |         |
|      | PCS valid after SCK | strong/50pf    |         | 15ns    |
|      | PCS valid after SCK | strong/50pf    | -4ns    |         |

**Table 34. DSPI high speed mode I/Os**

| DSPI  | High speed SCK | High speed SIN | High speed SOUT |
|-------|----------------|----------------|-----------------|
| DSPI2 | GPIO[78]       | GPIO[76]       | GPIO[77]        |
| DSPI3 | GPIO[100]      | GPIO[101]      | GPIO[98]        |
| SPI1  | GPIO[173]      | GPIO[175]      | GPIO[176]       |
| SPI2  | GPIO[79]       | GPIO[110]      | GPIO[111]       |

**Figure 7. DSPI classic SPI timing — master, CPHA = 0**

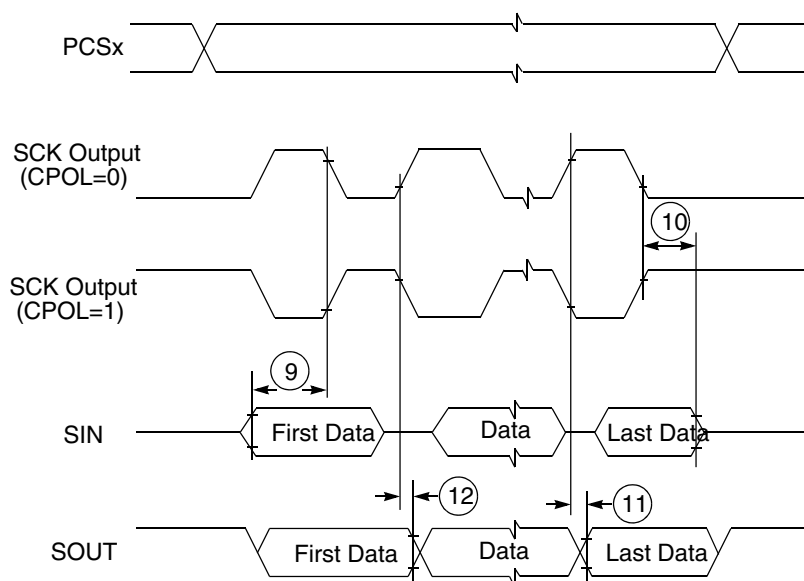


**Figure 8. DSPI classic SPI timing — master, CPHA = 1**

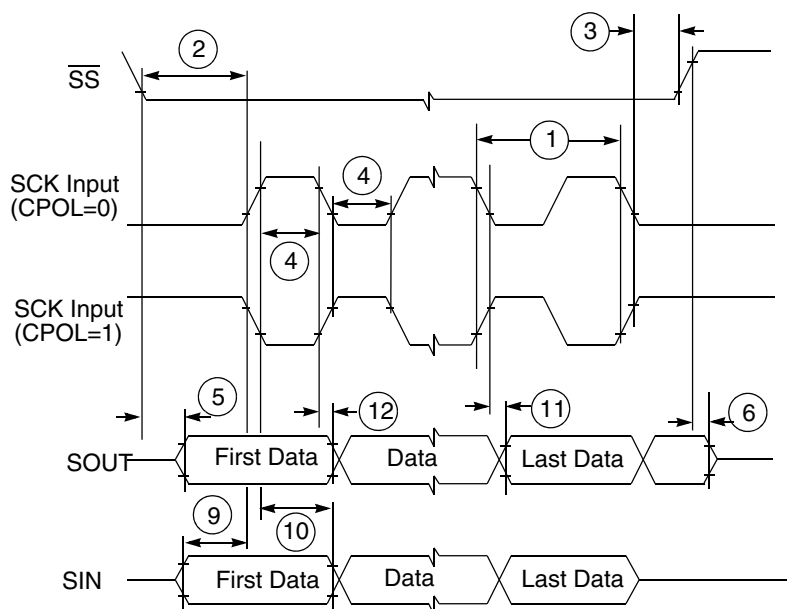


**Figure 9. DSPI classic SPI timing — slave, CPHA = 0**

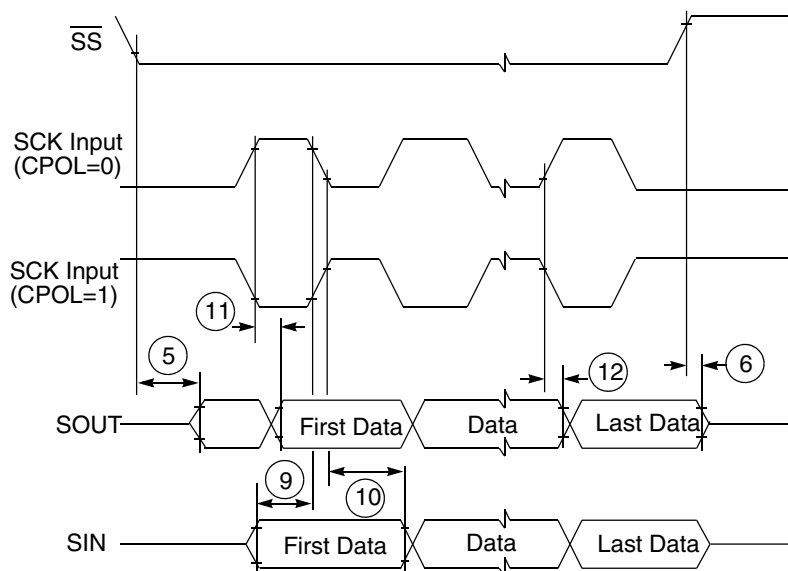


**Figure 10. DSPI classic SPI timing — slave, CPHA = 1**

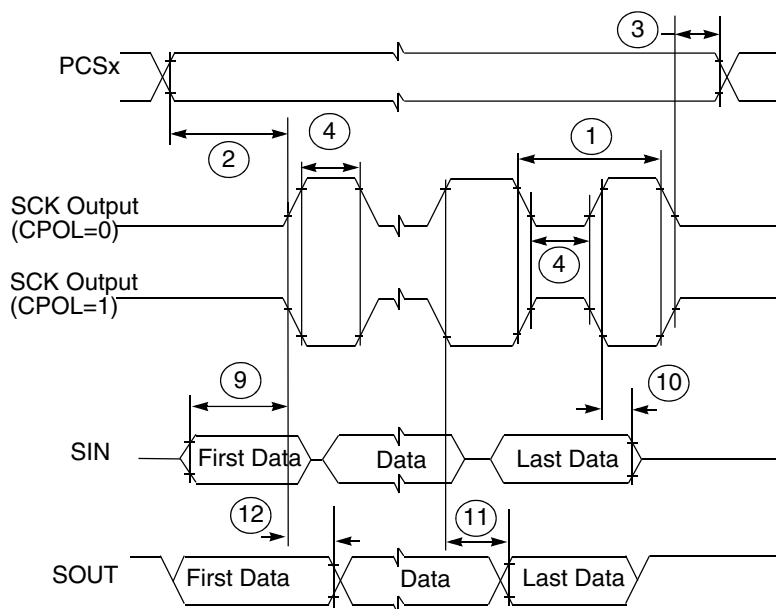


**Figure 11. DSPI modified transfer format timing — master, CPHA = 0**

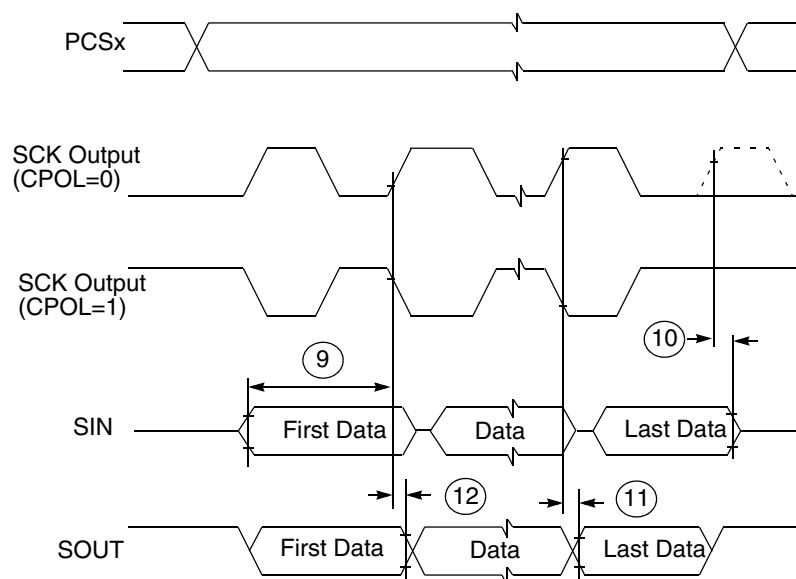


**Figure 12. DSPI modified transfer format timing — master, CPHA = 1**

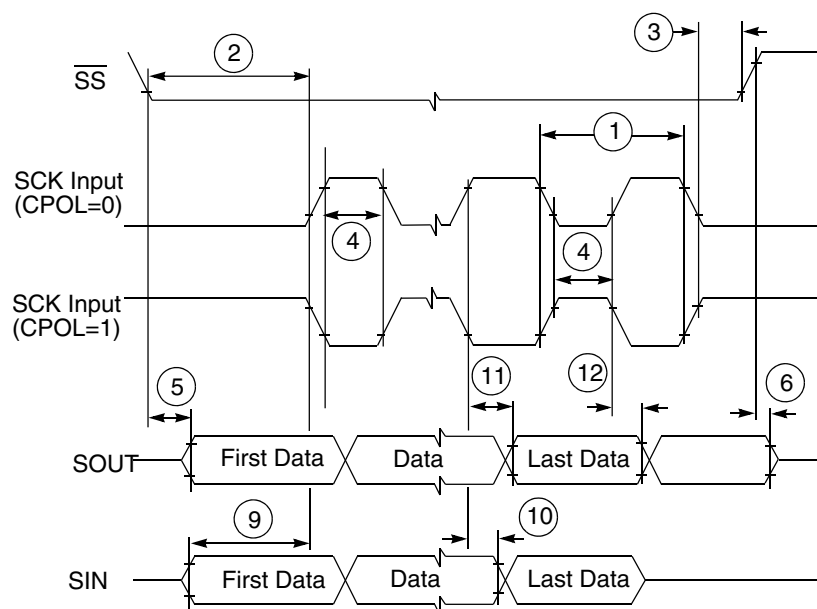


**Figure 13. DSPI modified transfer format timing – slave, CPHA = 0**

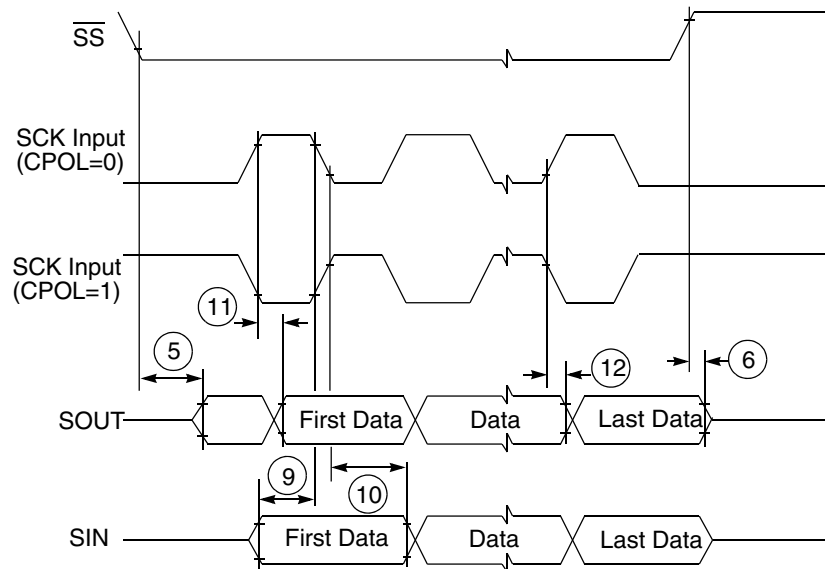


**Figure 14. DSPI modified transfer format timing — slave, CPHA = 1**

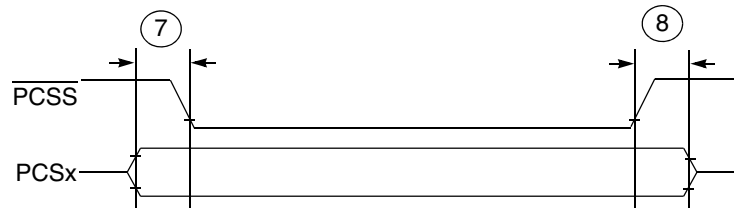


**Figure 15. DSPI PCS strobe (PCSS) timing**

## 4.4.2 FlexRay electrical specifications

### 4.4.2.1 FlexRay timing

This section provides the FlexRay Interface timing characteristics for the input and output signals. It should be noted that these are recommended numbers as per the FlexRay EPL v3.0 specification, and subject to change per the final timing analysis of the device.

### 4.4.2.2 TxEN

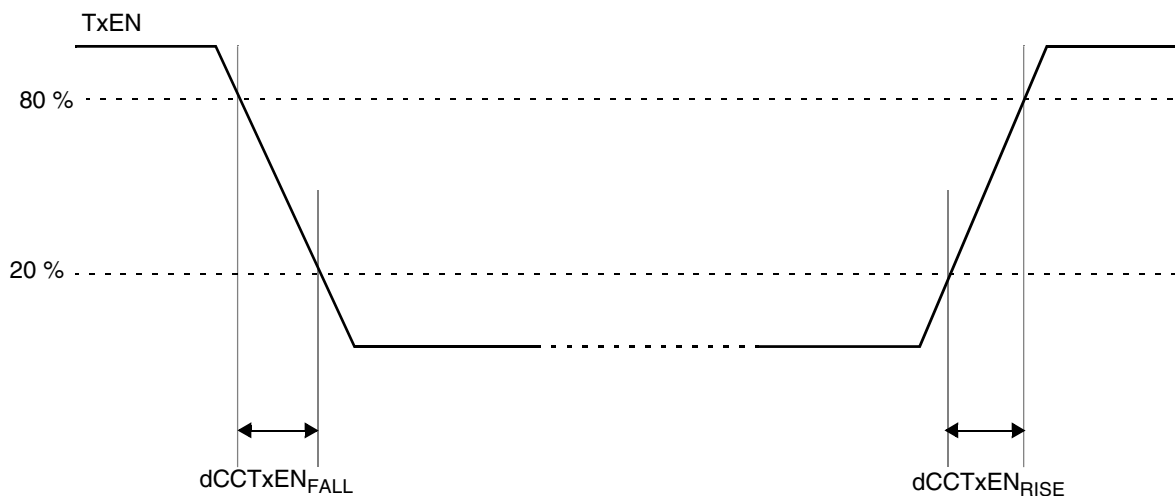


Figure 16. TxEN signal

Table 35. TxEN output characteristics<sup>1</sup>

| Name                      | Description                                                                            | Min | Max | Unit |
|---------------------------|----------------------------------------------------------------------------------------|-----|-----|------|
| dCCTxEN <sub>RISE25</sub> | Rise time of TxEN signal at CC                                                         |     | 9   | ns   |
| dCCTxEN <sub>FALL25</sub> | Fall time of TxEN signal at CC                                                         |     | 9   | ns   |
| dCCTxEN <sub>01</sub>     | Sum of delay between Clk to Q of the last FF and the final output buffer, rising edge  |     | 25  | ns   |
| dCCTxEN <sub>10</sub>     | Sum of delay between Clk to Q of the last FF and the final output buffer, falling edge |     | 25  | ns   |

1. All parameters specified for  $V_{DD\_HV\_IOx} = 3.3\text{ V} \pm 5\%, \pm 10\%$ ,  $T_J = -40\text{ }^{\circ}\text{C} / 150\text{ }^{\circ}\text{C}$ , TxEN pin load maximum 25 pF

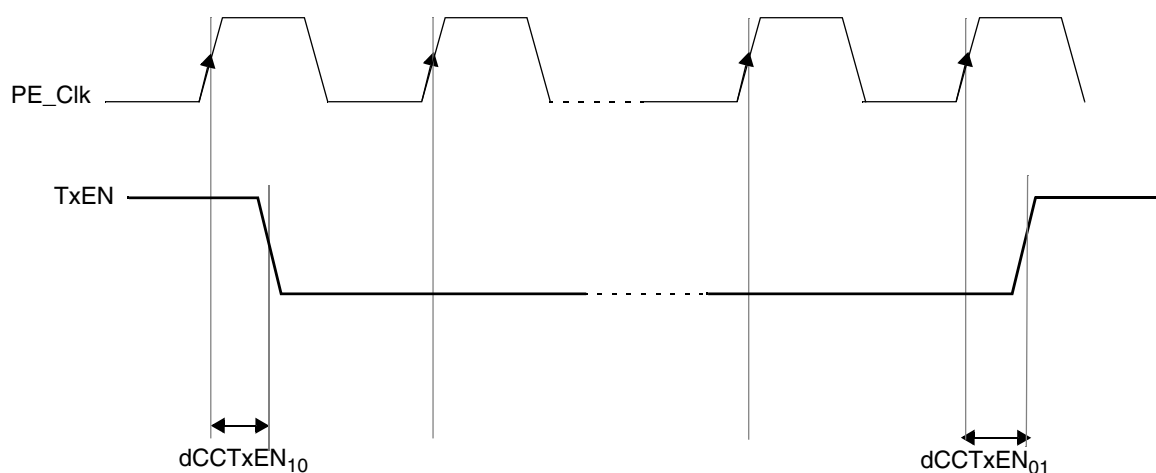


Figure 17. TxEN signal propagation delays

#### 4.4.2.3 TxD

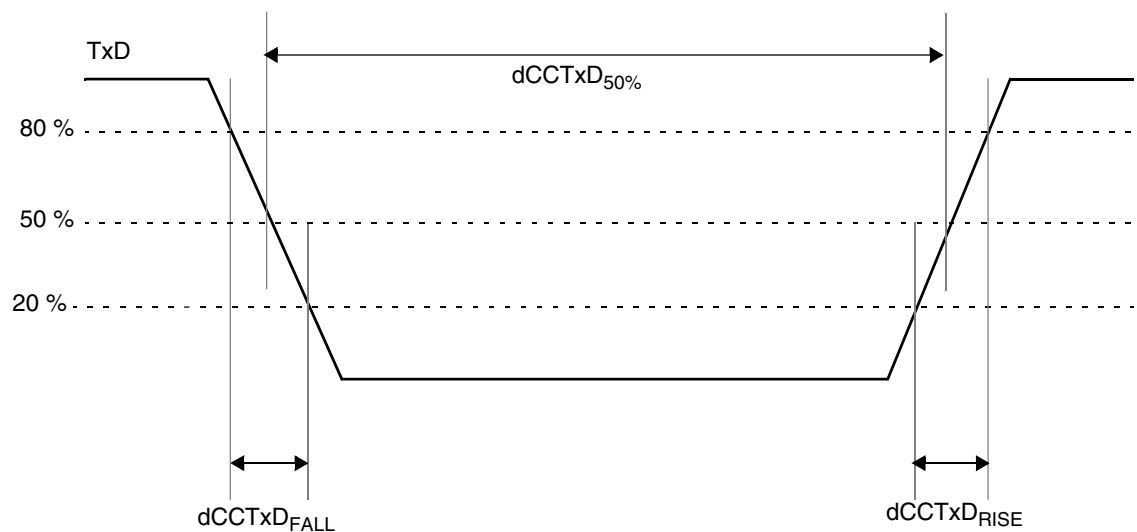


Figure 18. TxD Signal

Table 36. TxD output characteristics

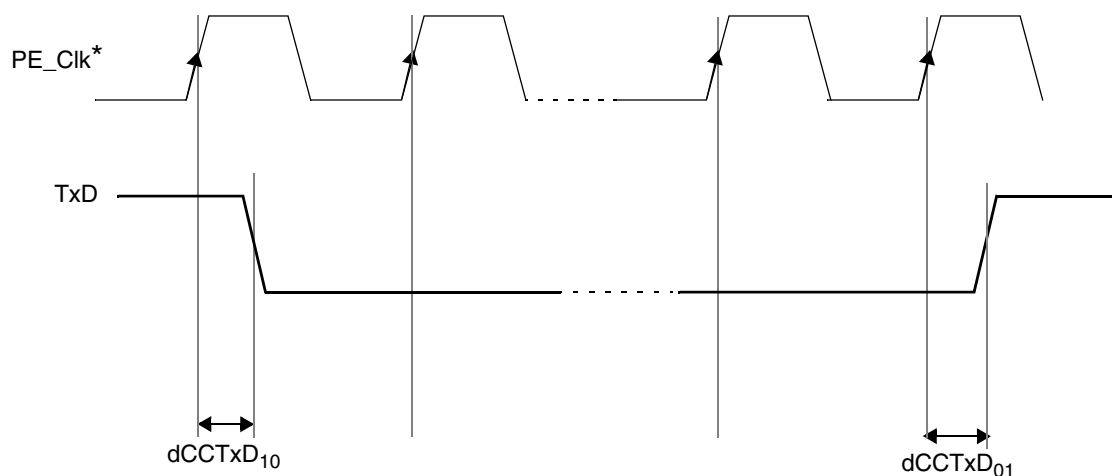
| Name                                               | Description <sup>1</sup>                                   | Min   | Max            | Unit |
|----------------------------------------------------|------------------------------------------------------------|-------|----------------|------|
| dCCT <sub>xAsym</sub>                              | Asymmetry of sending CC @ 25 pF load (=dCCTxD50% - 100 ns) | -2.45 | 2.45           | ns   |
| dCCTxD <sub>RISE25</sub> +dCCTxD <sub>FALL25</sub> | Sum of Rise and Fall time of TxD signal at the output      |       | 9 <sup>2</sup> | ns   |

Table continues on the next page...

**Table 36. TxD output characteristics (continued)**

| Name                 | Description <sup>1</sup>                                                               | Min | Max | Unit |
|----------------------|----------------------------------------------------------------------------------------|-----|-----|------|
| dCCTxD <sub>01</sub> | Sum of delay between Clk to Q of the last FF and the final output buffer, rising edge  |     | 25  | ns   |
| dCCTxD <sub>10</sub> | Sum of delay between Clk to Q of the last FF and the final output buffer, falling edge |     | 25  | ns   |

1. All parameters specified for  $V_{DD\_HV\_IOx} = 3.3\text{ V} \pm 5\%, \pm 10\%$ ,  $T_J = -40\text{ }^{\circ}\text{C} / 150\text{ }^{\circ}\text{C}$ , TxD pin load maximum 25 pF.
2. For  $3.3\text{ V} \pm 10\%$  operation, this specification is 10 ns.



\*FlexRay Protocol Engine Clock

**Figure 19. TxD Signal propagation delays**

#### 4.4.2.4 RxD

**Table 37. RxD input characteristic**

| Name                 | Description <sup>1</sup>                                                    | Min | Max | Unit |
|----------------------|-----------------------------------------------------------------------------|-----|-----|------|
| C_CCRxD              | Input capacitance on RxD pin                                                |     | 7   | pF   |
| uCCLogic_1           | Threshold for detecting logic high                                          | 35  | 70  | %    |
| uCCLogic_0           | Threshold for detecting logic low                                           | 30  | 65  | %    |
| dCCRxD <sub>01</sub> | Sum of delay from actual input to the D input of the first FF, rising edge  |     | 10  | ns   |
| dCCRxD <sub>10</sub> | Sum of delay from actual input to the D input of the first FF, falling edge |     | 10  | ns   |

1. All parameters specified for  $VDD\_HV\_IOx = 3.3\text{ V} \pm 5\%$ ,  $\pm 10\%$ ,  $T_J = -40\text{ }^{\circ}\text{C} / 150\text{ }^{\circ}\text{C}$ .

### 4.4.3 uSDHC specifications

**Table 38. uSDHC switching specifications**

| Num                                                                         | Symbol           | Description                           | Min. | Max. | Unit |
|-----------------------------------------------------------------------------|------------------|---------------------------------------|------|------|------|
| <b>Card input clock</b>                                                     |                  |                                       |      |      |      |
| SD1                                                                         | fpp              | Clock frequency (Identification mode) | 0    | 400  | kHz  |
|                                                                             | fpp              | Clock frequency (SD\SDIO full speed)  | 0    | 25   | MHz  |
|                                                                             | fpp              | Clock frequency (SD\SDIO high speed)  | 0    | 40   | MHz  |
|                                                                             | fpp              | Clock frequency (MMC full speed)      | 0    | 20   | MHz  |
|                                                                             | f <sub>OD</sub>  | Clock frequency (MMC full speed)      | 0    | 40   | MHz  |
| SD2                                                                         | t <sub>WL</sub>  | Clock low time                        | 7    | —    | ns   |
| SD3                                                                         | t <sub>WH</sub>  | Clock high time                       | 7    | —    | ns   |
| SD4                                                                         | t <sub>TLH</sub> | Clock rise time                       | —    | 3    | ns   |
| SD5                                                                         | t <sub>THL</sub> | Clock fall time                       | —    | 3    | ns   |
| <b>SDHC output / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b> |                  |                                       |      |      |      |
| SD6                                                                         | t <sub>OD</sub>  | SDHC output delay (output valid)      | -5   | 6.5  | ns   |
| <b>SDHC input / card inputs SDHC_CMD, SDHC_DAT (reference to SDHC_CLK)</b>  |                  |                                       |      |      |      |
| SD7                                                                         | t <sub>ISU</sub> | SDHC input setup time                 | 5    | —    | ns   |
| SD8                                                                         | t <sub>IH</sub>  | SDHC input hold time                  | 0    | —    | ns   |

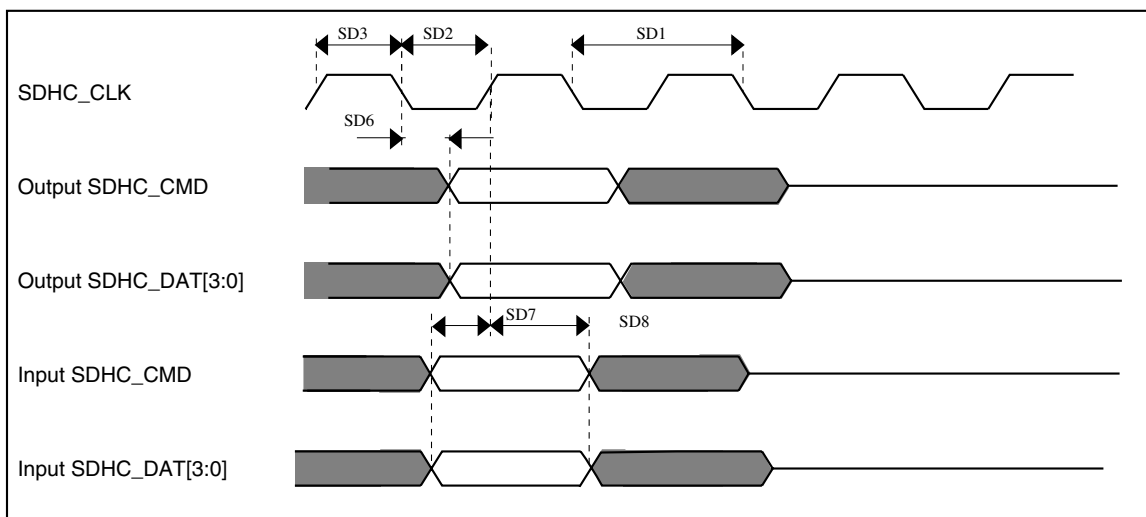


**Figure 20. uSDHC timing**

## 4.4.4 Ethernet switching specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

### 4.4.4.1 MII signal switching specifications

The following timing specs meet the requirements for MII style interfaces for a range of transceiver devices.

**Table 39. MII signal switching specifications**

| Symbol | Description                           | Min. | Max. | Unit         |
|--------|---------------------------------------|------|------|--------------|
| —      | RXCLK frequency                       | —    | 25   | MHz          |
| MII1   | RXCLK pulse width high                | 35%  | 65%  | RXCLK period |
| MII2   | RXCLK pulse width low                 | 35%  | 65%  | RXCLK period |
| MII3   | RXD[3:0], RXDV, RXER to RXCLK setup   | 5    | —    | ns           |
| MII4   | RXCLK to RXD[3:0], RXDV, RXER hold    | 5    | —    | ns           |
| —      | TXCLK frequency                       | —    | 25   | MHz          |
| MII5   | TXCLK pulse width high                | 35%  | 65%  | TXCLK period |
| MII6   | TXCLK pulse width low                 | 35%  | 65%  | TXCLK period |
| MII7   | TXCLK to TXD[3:0], TXEN, TXER invalid | 2    | —    | ns           |
| MII8   | TXCLK to TXD[3:0], TXEN, TXER valid   | —    | 25   | ns           |

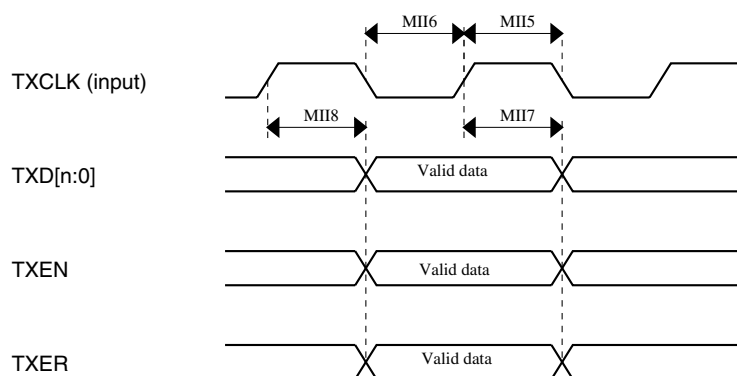


**Figure 21. RMII/MII transmit signal timing diagram**

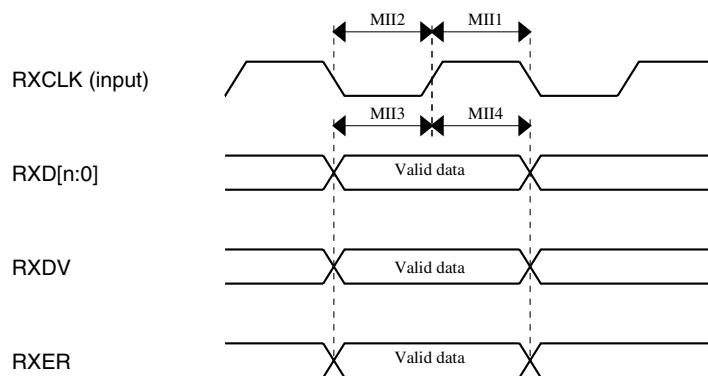


Figure 22. RMII/MII receive signal timing diagram

#### 4.4.4.2 RMII signal switching specifications

The following timing specs meet the requirements for RMII style interfaces for a range of transceiver devices.

Table 40. RMII signal switching specifications

| Num   | Description                                 | Min. | Max. | Unit            |
|-------|---------------------------------------------|------|------|-----------------|
| —     | EXTAL frequency (RMII input clock RMII_CLK) | —    | 50   | MHz             |
| RMII1 | RMII_CLK pulse width high                   | 35%  | 65%  | RMII_CLK period |
| RMII2 | RMII_CLK pulse width low                    | 35%  | 65%  | RMII_CLK period |
| RMII3 | RXD[1:0], CRS_DV, RXER to RMII_CLK setup    | 4    | —    | ns              |
| RMII4 | RMII_CLK to RXD[1:0], CRS_DV, RXER hold     | 2    | —    | ns              |
| RMII7 | RMII_CLK to TXD[1:0], TXEN invalid          | 4    | —    | ns              |
| RMII8 | RMII_CLK to TXD[1:0], TXEN valid            | —    | 15   | ns              |

#### 4.4.5 MediaLB (MLB) electrical specifications

##### 4.4.5.1 MLB 3-pin interface DC characteristics

The section lists the MLB 3-pin interface electrical characteristics.

Table 41. MediaLB 3-Pin Interface Electrical DC Specifications

| Parameter                 | Symbol   | Test Conditions | Min | Max | Unit |
|---------------------------|----------|-----------------|-----|-----|------|
| Maximum input voltage     | —        | —               | —   | 3.6 | V    |
| Low level input threshold | $V_{IL}$ | —               | —   | 0.7 | V    |

Table continues on the next page...

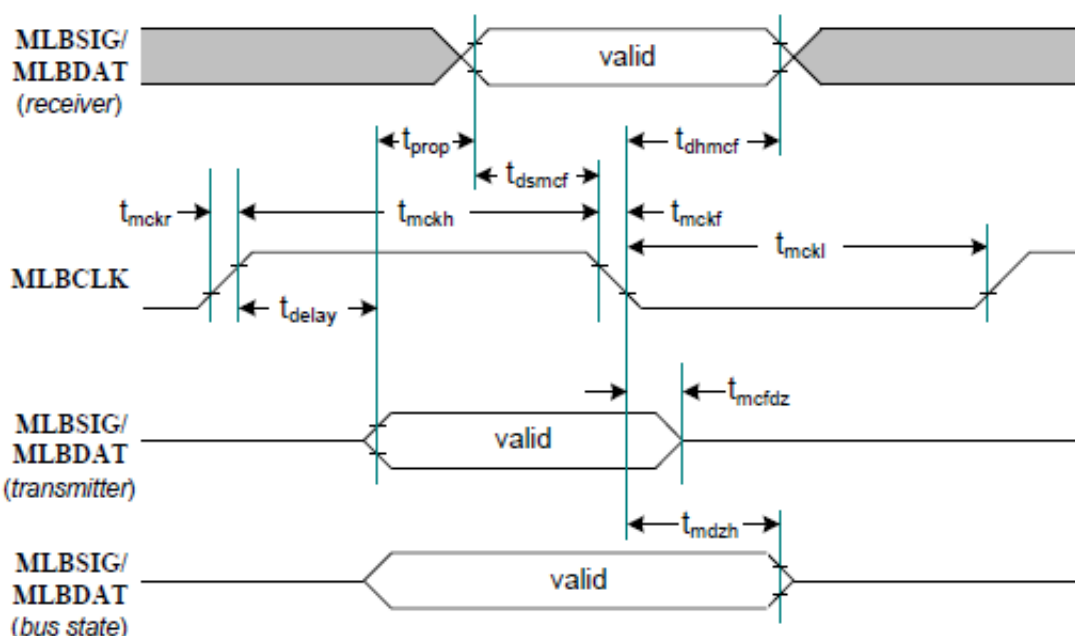
**Table 41. MediaLB 3-Pin Interface Electrical DC Specifications (continued)**

| Parameter                   | Symbol   | Test Conditions          | Min | Max      | Unit          |
|-----------------------------|----------|--------------------------|-----|----------|---------------|
| High level input threshold  | $V_{IH}$ | See Note <sup>1</sup>    | 1.8 | —        | V             |
| Low level output threshold  | $V_{OL}$ | $I_{OL} = -6 \text{ mA}$ | —   | 0.4      | V             |
| High level output threshold | $V_{OH}$ | $I_{OH} = -6 \text{ mA}$ | 2.0 | —        | V             |
| Input leakage current       | $I_L$    | $0 < V_{in} < V_{DD}$    | —   | $\pm 10$ | $\mu\text{A}$ |

1. Higher  $V_{IH}$  thresholds can be used; however, the risks associated with less noise margin in the system must be evaluated and assumed by the customer.

#### 4.4.5.2 MLB 3-pin interface electrical specifications

This section describes the timing electrical information of the MLB module.

**Figure 23. MediaLB 3-Pin Timing**

Ground = 0.0 V; Load Capacitance = 60 pF, input transition = 1 ns ; MediaLB speed = 256/512 Fs; Fs = 48 kHz; all timing parameters specified from the valid voltage threshold as listed below; unless otherwise noted.

**Table 42. MLB 3-Pin 256/512 Fs Timing Parameters**

| Parameter                  | Symbol     | Min    | Max  | Unit | Comment                                  |
|----------------------------|------------|--------|------|------|------------------------------------------|
| MLBCLK operating frequency | $f_{mck}$  | 11.264 | 25.6 | MHz  | 256x Fs at 44.0 kHz, 512x Fs at 50.0 kHz |
| MLBCLK rise time           | $t_{mckr}$ |        | 3    | ns   | $V_{IL}$ to $V_{IH}$                     |
| MLBCLK fall time           | $t_{mckf}$ |        | 3    | ns   | $V_{IH}$ to $V_{IL}$                     |

Table continues on the next page...

**Table 42. MLB 3-Pin 256/512 Fs Timing Parameters (continued)**

| Parameter                                            | Symbol      | Min         | Max        | Unit | Comment            |
|------------------------------------------------------|-------------|-------------|------------|------|--------------------|
| MLBCLK low time <sup>1</sup>                         | $t_{mckl}$  | 30<br>14    | —          | ns   | 256x Fs<br>512x Fs |
| MLBCLK high time                                     | $t_{mckh}$  | 30<br>14    | —          | ns   | 256x Fs<br>512x Fs |
| MLBSIG/MLBDAT receiver input setup to MLBCLK falling | $t_{dsmcf}$ | 1           | —          | ns   | —                  |
| MLBSIG/MLBDAT receiver input hold from MLBCLK low    | $t_{dhmcf}$ | $t_{mcfdz}$ | —          | ns   | —                  |
| MLBSIG/MLBDAT output valid from MLBCLK low           | $t_{mcfdz}$ | 0           | $t_{mckl}$ | ns   | 2                  |
| Bus output hold from MLBCLK low                      | $t_{mdzh}$  | 4           | —          | ns   | 2                  |

1. MLBCLK low/high time includes the pluse width variation.
2. The MediaLB driver can release the MLBDAT/MLBSIG line as soon as MLBCLK is low; however, the logic state of the final driven bit on the line must remain on the bus for  $t_{mdzh}$ . Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

Ground = 0.0 V; Load Capacitance = 40 pF, input transition = 1 ns; MediaLB speed = 1024 Fs; Fs = 48 kHz; all timing parameters specified from the valid voltage threshold as listed below; unless otherwise noted.

**Table 43. MLB 3-Pin 1024 Fs Timing Parameters**

| Parameter                                            | Symbol      | Min         | Max        | Unit       | Comment                                        |
|------------------------------------------------------|-------------|-------------|------------|------------|------------------------------------------------|
| MLBCLK Operating Frequency <sup>1</sup>              | $f_{mck}$   | 45.056<br>- | -<br>51.2  | MHz<br>MHz | 1024 x fs at 44.0 kHz<br>1024 x fs at 50.0 kHz |
| MLBCLK rise time                                     | $f_{mckr}$  |             | 1          | ns         | $V_{IL}$ to $V_{IH}$                           |
| MLBCLK fall time                                     | $f_{mckf}$  |             | 1          | ns         | $V_{IH}$ to $V_{IL}$                           |
| MLBCLK low time                                      | $t_{mckl}$  | 6.1         | —          | ns         | 2                                              |
| MLBCLK high time                                     | $t_{mckh}$  | 9.3         | —          | ns         | 2                                              |
| MLBSIG/MLBDAT receiver input setup to MLBCLK falling | $t_{dsmcf}$ | 1           | —          | ns         |                                                |
| MLBSIG/MLBDAT receiver input hold from MLBCLK low    | $t_{dhmcf}$ | $t_{mcfdz}$ | —          | ns         |                                                |
| MLBSIG/MLBDAT output valid from MLBCLK low           | $t_{mcfdz}$ | 0           | $t_{mckl}$ | ns         | 3                                              |
| Bus Hold from MLBCLK low                             | $t_{mdzh}$  | 2           | —          | ns         | 3                                              |

1. The controller can shut off MLBCLK to place MediaLB in a low-power state. Depending on the time the clock is shut off, a runt pulse can occur on MLBCLK.
2. MLBCLK low/high time includes the pluse width variation.

## USB electrical specifications

3. The MediaLB driver can release the MLBDAT/MLBSIG line as soon as MLBCLK is low; however, the logic state of the final driven bit on the line must remain on the bus for tmdzh. Therefore, coupling must be minimized while meeting the maximum load capacitance listed.

## 4.4.6 USB electrical specifications

### 4.4.6.1 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit <http://www.usb.org>.

### 4.4.6.2 ULPI timing specifications

The ULPI interface is fully compliant with the industry standard UTMI+ Low Pin Interface. Control and data timing requirements for the ULPI pins are given in the following table. These timings apply to synchronous mode only. All timings are measured with respect to the clock as seen at the USB\_CLKIN pin.

**Table 44. ULPI timing specifications**

| Num | Description                     | Min. | Typ.  | Max. | Unit |
|-----|---------------------------------|------|-------|------|------|
|     | USB_CLKIN operating frequency   | —    | 60    | —    | MHz  |
|     | USB_CLKIN duty cycle            | —    | 50    | —    | %    |
| U1  | USB_CLKIN clock period          | —    | 16.67 | —    | ns   |
| U2  | Input setup (control and data)  | 5    | —     | —    | ns   |
| U3  | Input hold (control and data)   | 1    | —     | —    | ns   |
| U4  | Output valid (control and data) | —    | —     | 9.5  | ns   |
| U5  | Output hold (control and data)  | 1    | —     | —    | ns   |

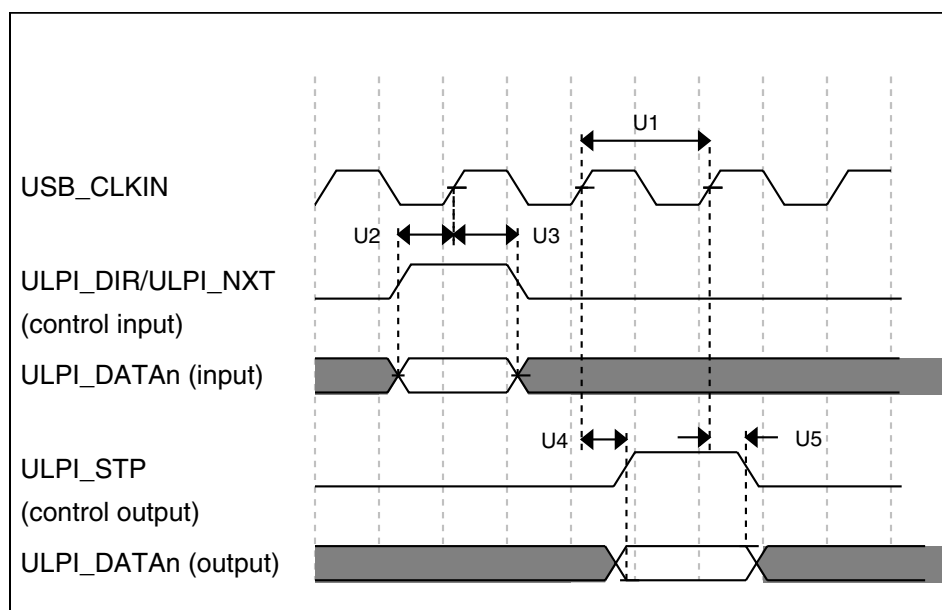


Figure 24. ULPI timing diagram

#### 4.4.7 SAI electrical specifications

All timing requirements are specified relative to the clock period or to the minimum allowed clock period of a device

Table 45. Master mode SAI Timing

| no  | Parameter                                  | Value |     | Unit        |
|-----|--------------------------------------------|-------|-----|-------------|
|     |                                            | Min   | Max |             |
|     | Operating Voltage                          | 2.7   | 3.6 | V           |
| S1  | SAI_MCLK cycle time                        | 40    | -   | ns          |
| S2  | SAI_MCLK pulse width high/low              | 45%   | 55% | MCLK period |
| S3  | SAI_BCLK cycle time                        | 80    | -   | BCLK period |
| S4  | SAI_BCLK pulse width high/low              | 45%   | 55% | ns          |
| S5  | SAI_BCLK to SAI_FS output valid            | -     | 15  | ns          |
| S6  | SAI_BCLK to SAI_FS output invalid          | 0     | -   | ns          |
| S7  | SAI_BCLK to SAI_TXD valid                  | -     | 15  | ns          |
| S8  | SAI_BCLK to SAI_TXD invalid                | 0     | -   | ns          |
| S9  | SAI_RXD/SAI_FS input setup before SAI_BCLK | 28    | -   | ns          |
| S10 | SAI_RXD/SAI_FS input hold after SAI_BCLK   | 0     | -   | ns          |

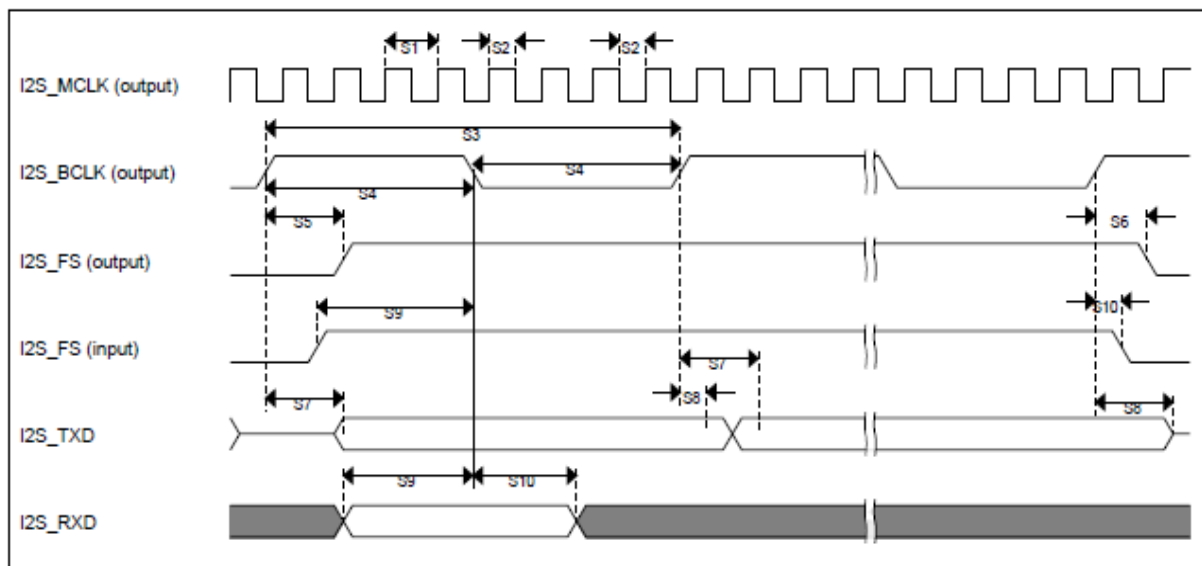


**Figure 3. SAI Timing — Master Modes**

**Figure 25. Master mode SAI Timing**

**Table 46. Slave mode SAI Timing**

| No  | Parameter                                 | Value |     | Unit        |
|-----|-------------------------------------------|-------|-----|-------------|
|     |                                           | Min   | Max |             |
|     | Operating Voltage                         | 2.7   | 3.6 | V           |
| S11 | SAI_BCLK cycle time (input)               | 80    | -   | ns          |
| S12 | SAI_BCLK pulse width high/low (input)     | 45%   | 55% | BCLK period |
| S13 | SAI_FS input setup before SAI_BCLK        | 10    | -   | ns          |
| S14 | SAI_FS input hold after SAI_BCLK          | 2     | -   | ns          |
| S15 | SAI_BCLK to SAI_TXD/SAI_FS output valid   | -     | 28  | ns          |
| S16 | SAI_BCLK to SAI_TXD/SAI_FS output invalid | 0     | -   | ns          |
| S17 | SAI_RXD setup before SAI_BCLK             | 10    | -   | ns          |
| S18 | SAI_RXD hold after SAI_BCLK               | 2     | -   | ns          |

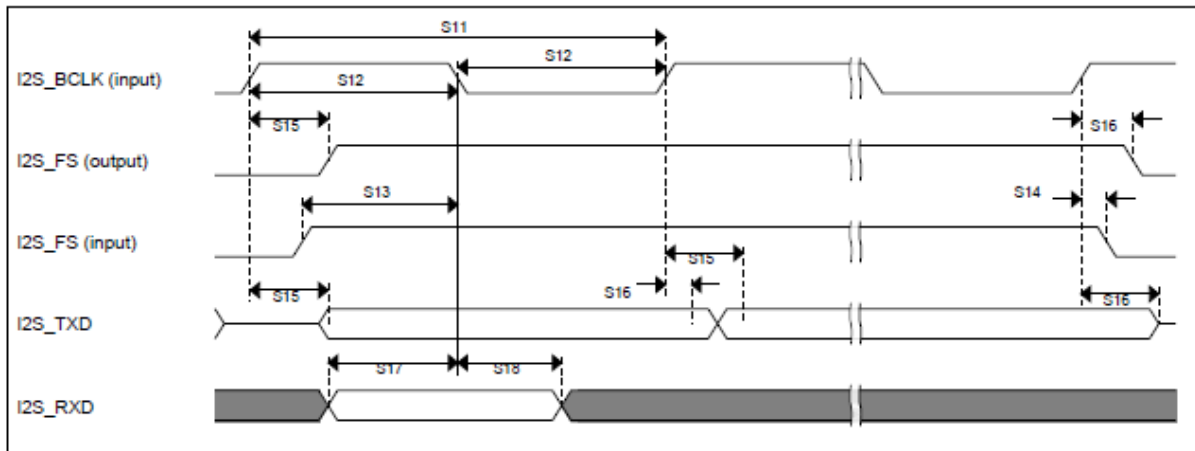


**Figure 26. Slave mode SAI Timing**

## 4.5 On-chip peripherals

### 4.5.1 On-chip peripherals

**Table 47. On-chip peripherals current consumption**

| Symbol          | Parameter                                | Conditions           |                                                                                                                                                                             | Value | Unit          |
|-----------------|------------------------------------------|----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|---------------|
| IDD_HV_A(CAN)   | CAN (FlexCAN) supply current on VDD_HV_A | 500 Kbps<br>125 Kbps | Total (static + dynamic) consumption: FlexCAN in loop-back mode XTAL@8 MHz used as CAN engine clock source Message sending period is 580 $\mu$ s                            | TBD   | $\mu$ A       |
| IDD_HV_A(eMIOS) | eMIOS supply current on VDD_HV_A         |                      | Static consumption: eMIOS channel OFF Global prescaler enabled<br><br>Dynamic consumption: It does not change varying the frequency (0.003 mA)                              | TBD   |               |
| IDD_HV_A(SCI)   | SCI (LINFlex) supply current on VDD_HV_A |                      | Total (static + dynamic) consumption: LIN mode Baudrate: 20 Kbps                                                                                                            | TBD   |               |
| IDD_HV_A(SPI)   | SPI (DSPI) supply current on VDD_HV_A    |                      | Ballast static consumption (only clocked)<br><br>Ballast dynamic consumption (continuous communication): Baudrate: 2 Mbit<br>Transmission every 8 $\mu$ s<br>Frame: 16 bits | TBD   |               |
| IDD_HV_A(ADC)   | ADC supply current on VDD_HV_A           | VDD = 5.5 V          | Ballast static consumption (no conversion)<br><br>Ballast dynamic consumption (continuous conversion)                                                                       | TBD   | mA            |
| IDD_HV_ADC0     | ADC_0 supply current on VDD_HV_ADC0      | VDD = 5.5 V          | Analog static consumption (no conversion)<br><br>Analog dynamic consumption (continuous conversion)                                                                         | TBD   | $\mu$ A<br>mA |
| IDD_HV_ADC1     | ADC_1 supply current on VDD_HV_ADC1      | VDD = 5.5 V          | Analog static consumption (no conversion)<br><br>Analog dynamic consumption (continuous conversion)                                                                         | TBD   | $\mu$ A<br>mA |

Table continues on the next page...

**Table 47. On-chip peripherals current consumption (continued)**

| Symbol        | Parameter                                    | Conditions  |   | Value | Unit |
|---------------|----------------------------------------------|-------------|---|-------|------|
| IDD_HV(FLASH) | CFlash + DFlash supply current on VDD_HV_ADC | VDD = 5.5 V | — | TBD   | mA   |
| IDD_HV(PLL)   | PLL supply current on VDD_HV                 | VDD = 5.5 V | — | TBD   |      |

## 4.6 Debug specifications

### 4.6.1 JTAG interface timing

**Table 48. JTAG pin AC electrical characteristics <sup>1</sup>**

| #  | Symbol                                | Characteristic                                         | Min  | Max              | Unit |
|----|---------------------------------------|--------------------------------------------------------|------|------------------|------|
| 1  | t <sub>JCYC</sub>                     | TCK Cycle Time <sup>2</sup>                            | 62.5 | —                | ns   |
| 2  | t <sub>JDC</sub>                      | TCK Clock Pulse Width                                  | 40   | 60               | %    |
| 3  | t <sub>TCKRISE</sub>                  | TCK Rise and Fall Times (40% - 70%)                    | —    | 3                | ns   |
| 4  | t <sub>TMS</sub> , t <sub>TDIS</sub>  | TMS, TDI Data Setup Time                               | 5    | —                | ns   |
| 5  | t <sub>TMSH</sub> , t <sub>TDIH</sub> | TMS, TDI Data Hold Time                                | 5    | —                | ns   |
| 6  | t <sub>TDOV</sub>                     | TCK Low to TDO Data Valid                              | —    | 20 <sup>3</sup>  | ns   |
| 7  | t <sub>TDOI</sub>                     | TCK Low to TDO Data Invalid                            | 0    | —                | ns   |
| 8  | t <sub>TDOHZ</sub>                    | TCK Low to TDO High Impedance                          | —    | 15               | ns   |
| 11 | t <sub>BSDV</sub>                     | TCK Falling Edge to Output Valid                       | —    | 600 <sup>4</sup> | ns   |
| 12 | t <sub>BSDVZ</sub>                    | TCK Falling Edge to Output Valid out of High Impedance | —    | 600              | ns   |
| 13 | t <sub>BSDHZ</sub>                    | TCK Falling Edge to Output High Impedance              | —    | 600              | ns   |
| 14 | t <sub>BSDST</sub>                    | Boundary Scan Input Valid to TCK Rising Edge           | 15   | —                | ns   |
| 15 | t <sub>BSDHT</sub>                    | TCK Rising Edge to Boundary Scan Input Invalid         | 15   | —                | ns   |

1. These specifications apply to JTAG boundary scan only.
2. This timing applies to TDI, TDO, TMS pins, however, actual frequency is limited by pad type for EXTEST instructions. Refer to pad specification for allowed transition frequency
3. Timing includes TCK pad delay, clock tree delay, logic delay and TDO output pad delay.
4. Applies to all pins, limited by pad slew rate. Refer to IO delay and transition specification and add 20 ns for JTAG delay.

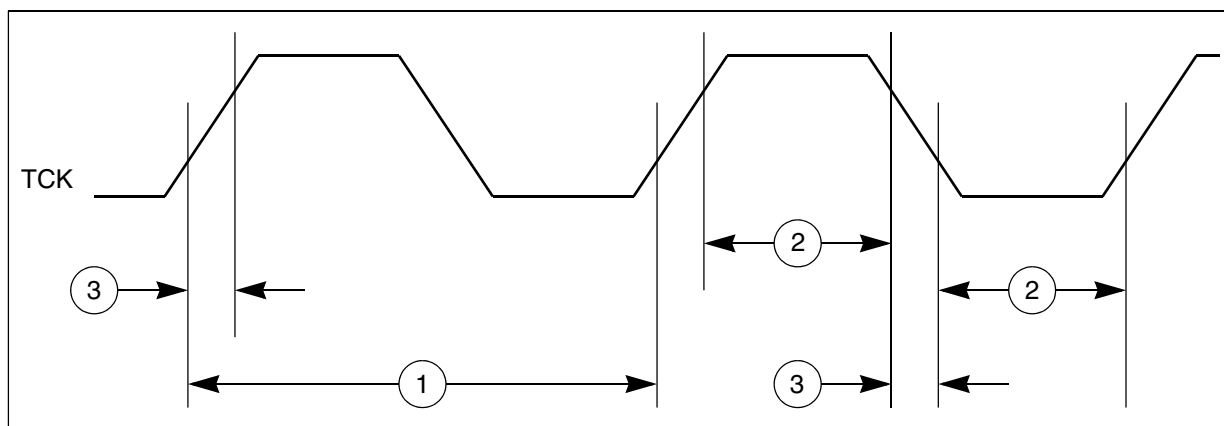


Figure 27. JTAG test clock input timing

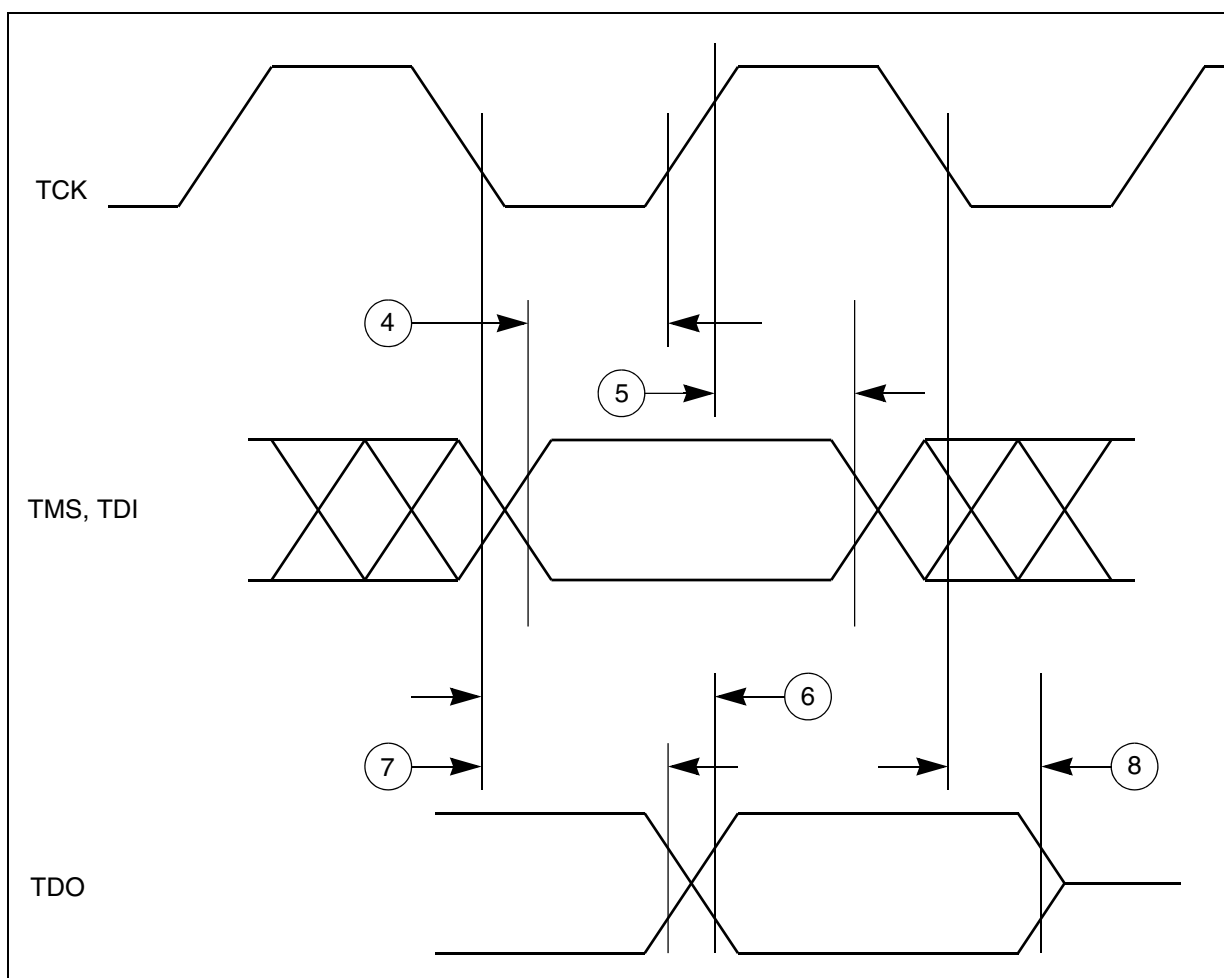


Figure 28. JTAG test access port timing

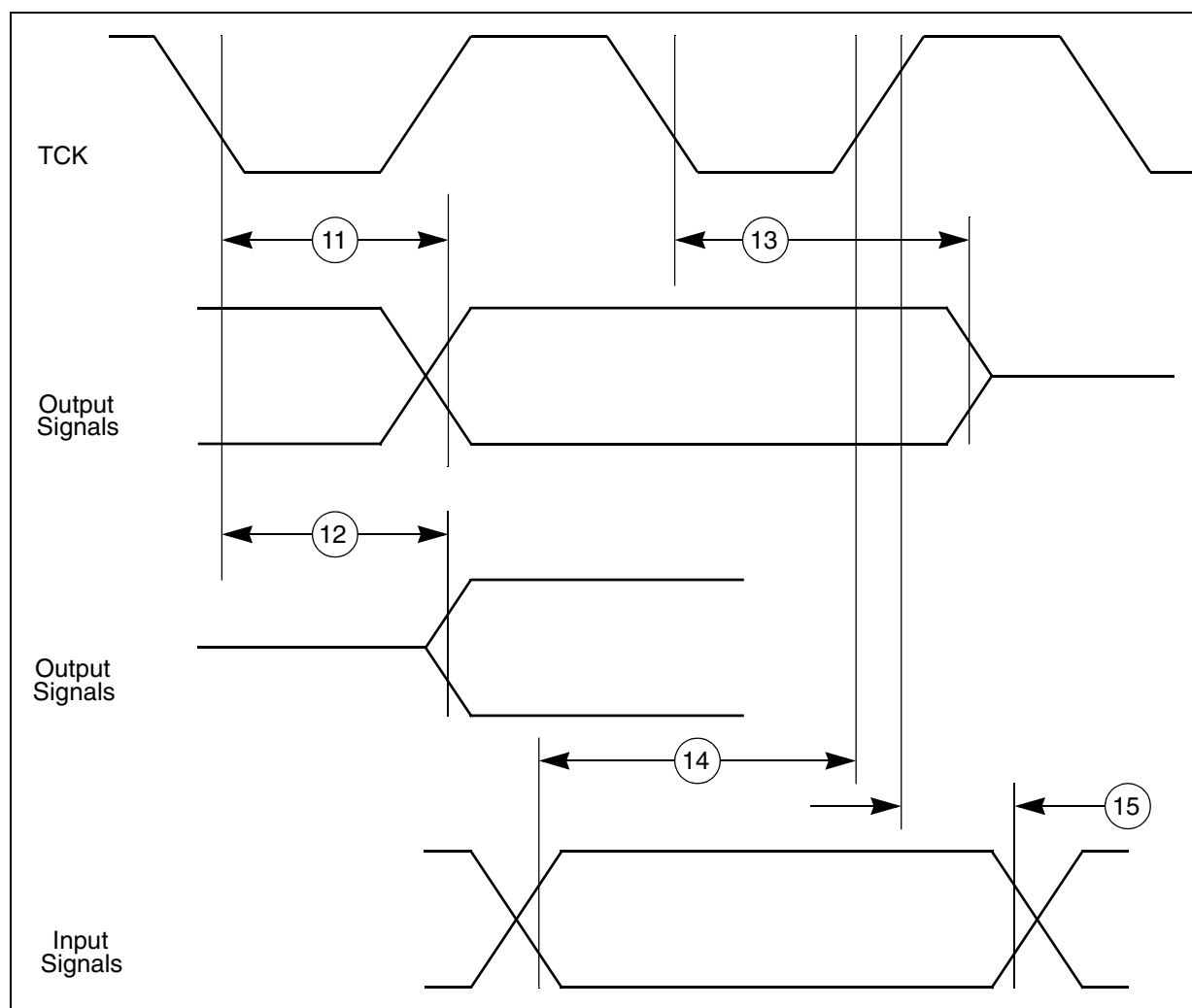


Figure 29. JTAG boundary scan timing

## 4.6.2 Nexus timing

Table 49. Nexus debug port timing <sup>1</sup>

| No. | Symbol                       | Parameter                                           | Conditions | Min  | Max  | Unit       |
|-----|------------------------------|-----------------------------------------------------|------------|------|------|------------|
| 1   | $t_{MCYC}$                   | MCKO Cycle Time                                     | —          | 15.6 | —    | ns         |
| 2   | $t_{MDC}$                    | MCKO Duty Cycle                                     | —          | 40   | 60   | %          |
| 3   | $t_{MDOV}$                   | MCKO Low to MDO, MSEO, EVTO Data Valid <sup>2</sup> | —          | -0.1 | 0.25 | $t_{MCYC}$ |
| 4   | $t_{EVTIPW}$                 | EVTI Pulse Width                                    | —          | 4    | —    | $t_{TCYC}$ |
| 5   | $t_{EVTOPW}$                 | EVTO Pulse Width                                    | —          | 1    | —    | $t_{MCYC}$ |
| 6   | $t_{TCYC}$                   | TCK Cycle Time <sup>3</sup>                         | —          | 62.5 | —    | ns         |
| 7   | $t_{TDC}$                    | TCK Duty Cycle                                      | —          | 40   | 60   | %          |
| 8   | $t_{NTDIS}$ ,<br>$t_{NTMSS}$ | TDI, TMS Data Setup Time                            | —          | 8    | —    | ns         |

Table continues on the next page...

**Table 49. Nexus debug port timing <sup>1</sup> (continued)**

| No. | Symbol                       | Parameter                     | Condition<br>s | Min | Max | Unit |
|-----|------------------------------|-------------------------------|----------------|-----|-----|------|
| 9   | $t_{NTDIH}$ ,<br>$t_{NTMSH}$ | TDI, TMS Data Hold Time       | —              | 5   | —   | ns   |
| 10  | $t_{JOV}$                    | TCK Low to TDO/RDY Data Valid | —              | 0   | 25  | ns   |

1. JTAG specifications in this table apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal.
2. For all Nexus modes except DDR mode, MDO,  $\overline{MSEO}$ , and  $\overline{EVTO}$  data is held valid until next MCKO low cycle.
3. The system clock frequency needs to be four times faster than the TCK frequency.

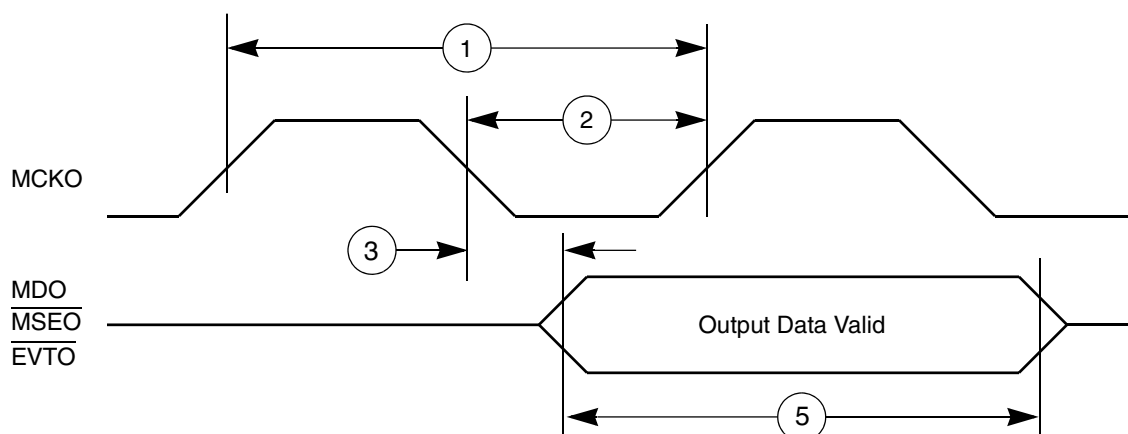


**Figure 30. Nexus output timing**

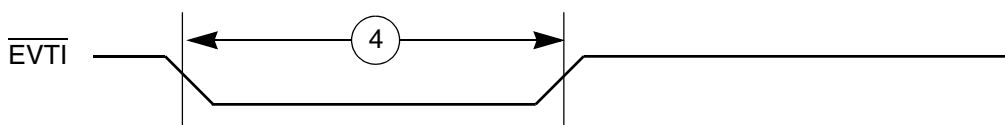


**Figure 31. Nexus EVTI Input Pulse Width**

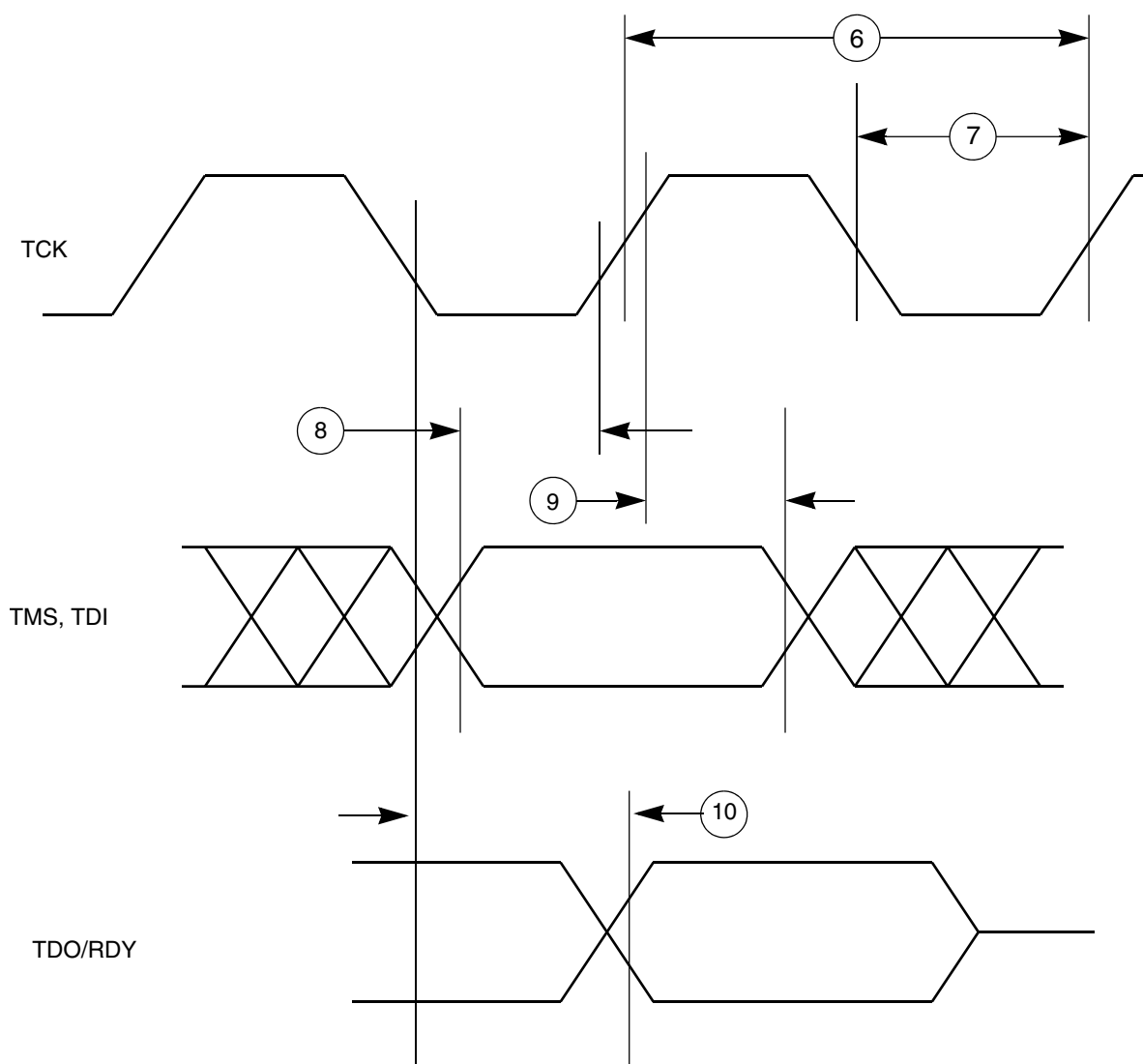


Figure 32. Nexus TDI, TMS, TDO timing

### 4.6.3 WKUP/NMI timing

Table 50. WKUP/NMI glitch filter

| No. | Symbol        | Parameter                        | Min | Typ | Max | Unit |
|-----|---------------|----------------------------------|-----|-----|-----|------|
| 1   | $W_{FNMI}$    | NMI pulse width that is rejected | —   | —   | 20  | ns   |
| 2   | $W_{NFNMI D}$ | NMI pulse width that is passed   | 400 | —   | —   | ns   |

## 4.6.4 External interrupt timing (IRQ pin)

Table 51. External interrupt timing specifications

| No. | Symbol     | Parameter             | Conditions | Min | Max | Unit      |
|-----|------------|-----------------------|------------|-----|-----|-----------|
| 1   | $t_{IPWL}$ | IRQ pulse width low   | —          | 3   | —   | $t_{CYC}$ |
| 2   | $t_{IPWH}$ | IRQ pulse width high  | —          | 3   | —   | $t_{CYC}$ |
| 3   | $t_{ICYC}$ | IRQ edge to edge time | —          | 6   | —   | $t_{CYC}$ |

These values apply when IRQ pins are configured for rising edge or falling edge events, but not both.

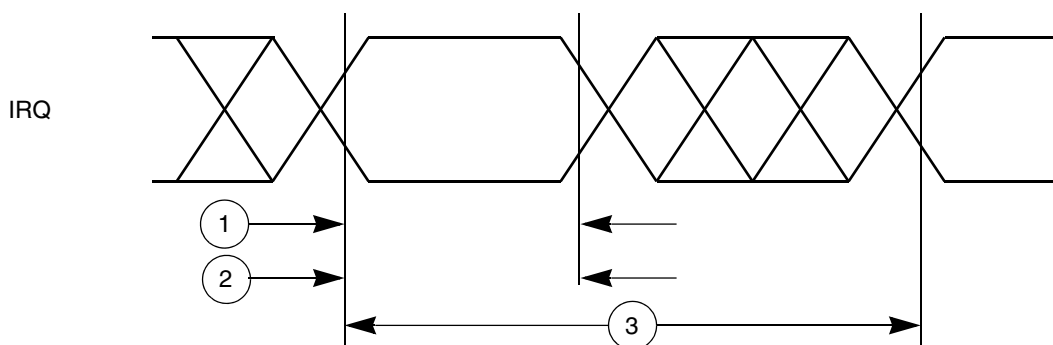


Figure 33. External interrupt timing

## 5 Thermal attributes

### 5.1 Thermal attributes

| Board type        | Symbol           | Description                                                      | 176LQFP | Unit                 | Notes |
|-------------------|------------------|------------------------------------------------------------------|---------|----------------------|-------|
| Single-layer (1s) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)     | 45      | $^{\circ}\text{C/W}$ | 1, 2  |
| Four-layer (2s2p) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)     | 22      | $^{\circ}\text{C/W}$ | 1, 3  |
| Single-layer (1s) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed) | 36      | $^{\circ}\text{C/W}$ | 1, 3  |

Table continues on the next page...

| Board type        | Symbol                | Description                                                      | 176LQFP | Unit | Notes |
|-------------------|-----------------------|------------------------------------------------------------------|---------|------|-------|
| Four-layer (2s2p) | $R_{\theta JA}$       | Thermal resistance, junction to ambient (200 ft./min. air speed) | 16      | °C/W | 4     |
| —                 | $R_{\theta JB}$       | Thermal resistance, junction to board                            | 11      | °C/W | 5     |
| —                 | $R_{\theta JCtop}$    | Thermal resistance, junction to case top                         | 8       | °C/W | 6     |
| —                 | $R_{\theta JCbottom}$ | Thermal resistance, junction to case bottom                      | 0.5     | °C/W | 7     |
| —                 | $\Psi_{JT}$           | Thermal characterization parameter, junction to package top      | 1       | °C/W | 8     |

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance
2. Per JEDEC JESD51-2 with the single layer board (JESD51-3) horizontal.
3. Per JEDEC JESD51-6 with the board (JESD51-7) horizontal.

| Board type        | Symbol           | Description                                                                     | 324 MAPBGA | Unit | Notes  |
|-------------------|------------------|---------------------------------------------------------------------------------|------------|------|--------|
| Single-layer (1s) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)                    | 25.5       | °C/W | 1, 2   |
| Four-layer (2s2p) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)                    | 19.0       | °C/W | 1,2, 3 |
| Single-layer (1s) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                | 18.1       | °C/W | 13     |
| Four-layer (2s2p) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                | 14.8       | °C/W | 1,3    |
| —                 | $R_{\theta JB}$  | Thermal resistance, junction to board                                           | 10.4       | °C/W | 4      |
| —                 | $R_{\theta JC}$  | Thermal resistance, junction to case                                            | 8.4        | °C/W | 5      |
| —                 | $\Psi_{JT}$      | Thermal characterization parameter, junction to package top natural convection) | 0.45       | °C/W | 6      |

Table continues on the next page...

## Thermal attributes

| Board type | Symbol      | Description                                                                      | 324 MAPBGA | Unit | Notes |
|------------|-------------|----------------------------------------------------------------------------------|------------|------|-------|
| —          | $\Psi_{JB}$ | Thermal characterization parameter, junction to package top (natural convection) | 2.65       | °C/W | 7     |

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.,
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.
7. Thermal characterization parameter indicating the temperature difference between package bottom center and the junction temperature per JEDEC JESD51-12. When Greek letters are not available, the thermal characterization parameter is written as Psi-JB.

| Board type        | Symbol           | Description                                                                                     | 256 MAPBGA | Unit | Notes  |
|-------------------|------------------|-------------------------------------------------------------------------------------------------|------------|------|--------|
| Single-layer (1s) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)                                    | 29.4       | °C/W | 1, 2   |
| Four-layer (2s2p) | $R_{\theta JA}$  | Thermal resistance, junction to ambient (natural convection)                                    | 19.3       | °C/W | 1,2, 3 |
| Single-layer (1s) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | 21.4       | °C/W | 1,3    |
| Four-layer (2s2p) | $R_{\theta JMA}$ | Thermal resistance, junction to ambient (200 ft./min. air speed)                                | 14.8       | °C/W | 1,3    |
| —                 | $R_{\theta JB}$  | Thermal resistance, junction to board                                                           | 11         | °C/W | 4      |
| —                 | $R_{\theta JC}$  | Thermal resistance, junction to case                                                            | 9.5        | °C/W | 5      |
| —                 | $\Psi_{JT}$      | Thermal characterization parameter, junction to package top outside center (natural convection) | 0.5        | °C/W | 6      |

Table continues on the next page...

| Board type | Symbol      | Description                                                                                     | 256 MAPBGA | Unit | Notes |
|------------|-------------|-------------------------------------------------------------------------------------------------|------------|------|-------|
| —          | $\Psi_{JB}$ | Thermal characterization parameter, junction to package top outside center (natural convection) | 2.8        | °C/W | 7     |

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.,
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.
7. Thermal characterization parameter indicating the temperature difference between package bottom center and the junction temperature per JEDEC JESD51-12. When Greek letters are not available, the thermal characterization parameter is written as Psi-JB.

## 6 Dimensions

### 6.1 Obtaining package dimensions

Package dimensions are provided in package drawing.

To find a package drawing, go to [www.freescale.com](http://www.freescale.com) and perform a keyword search for the drawing's document number:

| Package      | Freescall Document Number |
|--------------|---------------------------|
| 176-pin LQFP | 98ASA00673D               |
| 256 MAPBGA   | 98ASA00346D               |
| 324 MAPBGA   | 98ASA10582D               |

## 7 Pinouts

### 7.1 Package pinouts and signal descriptions

For package pinouts and signal descriptions, refer to the Reference Manual.

## 8 Revision History

The following table provides a revision history for this document.

**Table 52. Revision History**

| Rev. No. | Date          | Substantial Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
|----------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Rev1     | 14 March 2013 | Initial Release                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| Rev1.1   | 16 May 2013   | Updated Pinouts section                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| Rev2     | 22 May 2014   | <ul style="list-style-type: none"> <li>Removed Category (SR, CC, P, T, D, B) column from all the table of the Datasheet</li> <li>Revised the feature list.</li> <li>Revised Introduction section to remove classification information.</li> <li>Updated optional information in the ordering information figure.</li> <li>Revised Absolute maximum rating section: <ul style="list-style-type: none"> <li>Removed category column from table</li> <li>Added footnote at Ta</li> </ul> </li> <li>Revised Recommended operating conditions section <ul style="list-style-type: none"> <li>Added notes</li> <li>Updated table: Recommended operating conditions (VDD_HV_x = 3.3 V)</li> <li>Updated table: Recommended operating conditions (VDD_HV_x = 5 V)</li> </ul> </li> <li>Revised Voltage regulator electrical characteristics <ul style="list-style-type: none"> <li>Updated text describing bipolar transistors</li> <li>Updated figure: Voltage regulator capacitance connection</li> <li>Updated table: Voltage regulator electrical specifications</li> <li>Removed Brownout information</li> </ul> </li> <li>Revised Voltage monitor electrical characteristics table</li> </ul> |

*Table continues on the next page...*

Table 52. Revision History (continued)

| Rev. No. | Date | Substantial Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
|----------|------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|          |      | <ul style="list-style-type: none"> <li>Revised Supply current characteristics section               <ul style="list-style-type: none"> <li>Updated table: Current consumption characteristics</li> <li>Updated table: Low Power Unit (LPU) Current consumption characteristics</li> <li>STANDBY Current consumption characteristics</li> </ul> </li> <li>Revised Electromagnetic Interference (EMI) characteristics section</li> <li>Revised DC electrical specifications @ 3.3V Range table for naming conventions.</li> <li>Revised DC electrical specifications @ 5 V Range table for naming conventions</li> <li>Deleted MLB 6-pin Electrical Specifications</li> <li>Removed PORST characteristics from Functional reset pad electrical characteristics table</li> <li>Added section PORST electrical characteristics</li> <li>Revised Input impedance and ADC accuracy section to remove SNR, THD, SINAD, ENOB,</li> <li>Revised 32 kHz oscillator electrical specifications table to remove 'Vpp' row.</li> <li>Updated 16 MHz RC Oscillator electrical specifications table for statuptime, cycle to cycle jitter, and lonf term jitter</li> <li>Updated 128 KHz Internal RC oscillator electrical specifications table.</li> <li>Updated PLL electrical specifications table</li> <li>Added Jitter Calculation table</li> <li>Added Percentage of Sample exceeding specified value of jitter table</li> </ul> |

Table continues on the next page...

Table 52. Revision History (continued)

| Rev. No. | Date | Substantial Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |
|----------|------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
|          |      | <ul style="list-style-type: none"> <li>Revised Memory interfaces section</li> <li>Revised Communication interfaces section               <ul style="list-style-type: none"> <li>Updated note</li> <li>Added Continuous SCK timing table</li> <li>Added DSPI high speed mode I/Os table</li> </ul> </li> <li>Updated input transition value in section MLB 3-pin interface electrical specifications</li> <li>Deleted MLB 6-pin interface DC characteristics section</li> <li>Deleted MLB 6-pin interface AC characteristics section</li> <li>Updated JTAG pin AC electrical characteristics table</li> <li>Revised table under Thermal attributes section</li> <li>Updated Obtaining package dimensions section for Freescale Document numbers</li> </ul> |

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